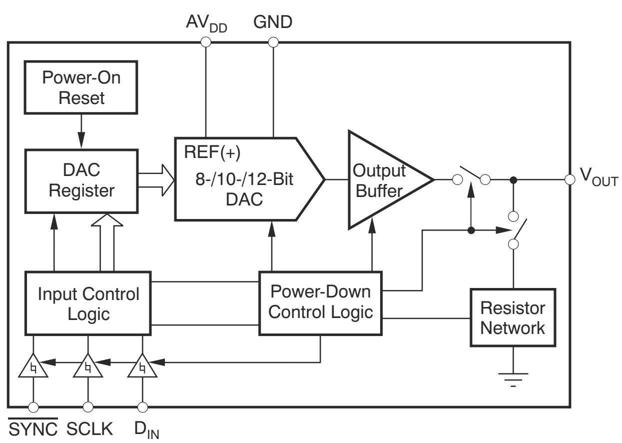
DACx311 2-V to 5.5-V, 80-µA, 8-Bit, 10-Bit, and 12-Bit, Low-Power, Single-Channel, Digital-to-Analog Converters in SC70 Package

1 Features

- Relative accuracy:
  - 0.25 LSB INL (DAC5311: 8-bit)
  - 0.5 LSB INL (DAC6311: 10-bit)
  - 1 LSB INL (DAC7311: 12-bit)
- *micro*Power operation: 80 µA at 2.0 V
- Power-down: 0.5 µA at 5 V, 0.1 µA at 2.0 V
- Wide power supply: 2.0 V to 5.5 V
- Power-on reset to zero scale
- Straight binary data format
- Low power serial interface with Schmitt-triggered inputs: up to 50 MHz
- On-chip output buffer amplifier, rail-to-rail operation
- $\overline{\text{SYNC}}$ interrupt facility
- Extended temperature range –40°C to +125°C
- Pin-compatible family in a tiny, 6-pin SC70 package

2 Applications

- Portable, battery-powered instruments
- 4-mA to 20-mA loop-powered applications
- Process control and industrial automation
- Programmable voltage and current sources



Simplified Schematic

3 Description

The 8-bit DAC5311, 10-bit DAC6311, and 12-bit DAC7311 (DACx311) are low-power, single-channel, voltage output digital-to-analog converters (DACs). The low power consumption in normal operation (0.55 mW at 5 V, reducing to 2.5 µW in power-down mode) makes the DACx311 an excellent choice for portable, battery-operated applications.

These devices are monotonic by design, provide excellent linearity, and minimize undesired code-to-code transient voltages while offering an easy upgrade path within a pin-compatible family. All devices use a versatile, three-wire serial interface that operates at clock rates of up to 50 MHz, and is compatible with standard SPI, QSPI, Microwire, and digital signal processor (DSP) interfaces.

All devices use an external power supply as a reference voltage to set the output range. The devices incorporate a power-on reset (POR) circuit that powers up the DAC output at 0 V and remains at 0 V until a valid write to the device occurs. The DACx311 contain a power-down feature, accessed over the serial interface, that reduces current consumption of the device to 0.1 µA at 2.0 V in power-down mode.

These devices are pin-compatible with the DAC8311 and DAC8411, offering an easy upgrade path from 8-bit, 10-bit, and 12-bit resolution to 14-bit and 16-bit. All devices are available in a small, 6-pin, SC70 (SOT) package. This package offers a flexible, pin- and function-compatible, drop-in DAC within the family over an extended temperature range of –40°C to +125°C.

Device Information(1)

PART NUMBER(2)	RESOLUTION	PACKAGE SIZE(3)
DAC7311	12-bit	DCK (SC70, 6) 2 mm × 1.5 mm
DAC6311	10-bit	
DAC5311	8-bit	

(1) For all available packages, see the package option addendum at the end of the data sheet.
(2) See the *Device Comparison Tables*.
(3) The package size (length × width) is a nominal value and includes pins, where applicable.

Table of Contents

4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision C (July 2015) to Revision D (August 2023) — **Page**

- Updated the numbering format for tables, figures, and cross-references throughout the document..... 1
- Changed Device Information table to show package size instead of body size and added content to show difference among devices.....1
- Changed power dissipation max value for normal mode at AV_{DD} = 3.6 V to 5.5 V from 0.88 mW to 0.99 mW in *Electrical Characteristics* 5
- Changed I_{DD} max value for normal mode at AV_{DD} = 3.6 V to 5.5 V from 160 µA to 180 µA in *Electrical Characteristics* 5

Changes from Revision B (May 2013) to Revision C (July 2015) — **Page**

- Added *ESD Ratings* table, and *Feature Description*, *Device Functional Modes*, *Application and Implementation*, *Power Supply Recommendations*, *Layout*, *Device and Documentation Support*, and *Mechanical, Packaging, and Orderable Information* sections..... 1
- Added *Device Comparison* section and moved existing tables to this new section..... 3
- Moved *Operating Temperature* parameter from *Electrical Characteristics* table to *Recommended Operating Conditions* table 4
- Deleted *Parameter Definitions* section; definitions moved to new *Glossary* section..... 32

Changes from Revision A (August 2011) to Revision B (May 2013) — **Page**

- Changed all 1.8 V to 2.0 V throughout data sheet..... 1
- Deleted the 1.8-V Typical Characteristics section..... 8
- Changed X-axis for Figure 7-36, Power-Supply Current vs Power-Supply Voltage..... 8
- Changed X-axis for Figure 7-37, Power-Down Current vs Power-Supply Voltage.....8

Changes from Revision * (August, 2008) to Revision A (August, 2011) — **Page**

- Changed specifications and test conditions for input low voltage parameter..... 5
- Changed specifications and test conditions for input high voltage parameter.....5

5 Device Comparison

Table 5-1. Related Devices

RELATED DEVICES	16-BIT	14-BIT	12-BIT	10-BIT	8-BIT
Pin and Function Compatible	DAC8411	DAC8311	DAC7311	DAC6311	DAC5311

Table 5-2. Relative Accuracy and Differential Nonlinearity

DEVICE	MAXIMUM RELATIVE ACCURACY (LSB)	MAXIMUM DIFFERENTIAL NONLINEARITY (LSB)
DAC5311	±0.25	±0.25
DAC6311	±0.5	±0.5
DAC7311	±1	±1

6 Pin Configuration and Functions

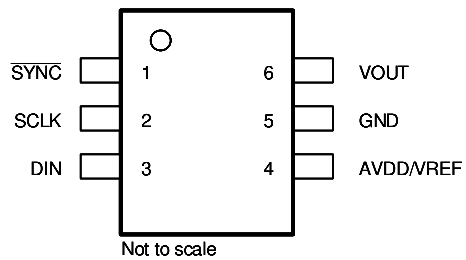


Figure 6-1. DCK Package, 6-Pin SC70 (Top View)

Table 6-1. Pin Functions

PIN		TYPE	DESCRIPTION
NAME	NO.		
AV_{DD}/V_{REF}	4	Input	Power supply input, 2.0 V to 5.5 V.
D_{IN}	3	Input	Serial Data Input. Data are clocked into the 16-bit input shift register on the falling edge of the serial clock input.
GND	5	—	Ground reference point for all circuitry on the part.
SCLK	2	Input	Serial clock input. Data are transferred at rates up to 50 MHz.
$\overline{\text{SYNC}}$	1	Input	Level-triggered control input (active low). This pin is the frame synchronization signal for the input data. When $\overline{\text{SYNC}}$ goes low, the input shift register is enabled and data are transferred in on the falling edges of the following clocks. The DAC is updated following 16th clock cycle, unless $\overline{\text{SYNC}}$ is taken high before this edge, in which case the rising edge of $\overline{\text{SYNC}}$ acts as an interrupt and the write sequence is ignored by the DACx311. See the *SYNC Interrupt* section for more details.
V_{OUT}	6	Output	Analog output voltage from DAC. The output amplifier has rail-to-rail operation.

7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) [(1)]

			MIN	MAX	UNIT
	Voltage	AV_{DD} to GND	–0.3	+6	V
		Digital input voltage to GND	–0.3	$+AV_{DD}$ + 0.3	V
		V_{OUT} to GND	–0.3	$+AV_{DD}$ + 0.3	V
T_J	Junction temperature			150	°C
T_{stg}	Storage temperature		–65	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001[(1)]	±1000	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101[(2)]	±500	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
T_A	Operating temperature	–40		125	°C
AV_{DD}	Supply voltage	2		5.5	V

7.4 Thermal Information

THERMAL METRIC[(1)]		DACx311 DCK (SC70) 6 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	216.4	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	52.1	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	65.9	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	1.3	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	65.2	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the application report, *Semiconductor and IC Package Thermal Metrics* application note.

7.5 Electrical Characteristics

at AV_{DD} = 2.0 V to 5.5 V, R_L = 2 kΩ to GND, C_L = 200 pF to GND, and T_A = –40°C to +125°C (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
STATIC PERFORMANCE[1]						
DAC5311	Resolution		8			Bits
DAC6311	Resolution		10			Bits
DAC7311	Resolution		12			Bits
DAC5311	Relative accuracy	Measured by the line passing through codes 3 and 252		±0.01	±0.25	LSB
DAC6311	Relative accuracy	Measured by the line passing through codes 12 and 1012		±0.06	±0.5	LSB
DAC7311	Relative accuracy	Measured by the line passing through codes 30 and 4050		±0.3	±1	LSB
DAC5311	Differential nonlinearity			±0.01	±0.25	LSB
DAC6311	Differential nonlinearity			±0.03	±0.5	LSB
DAC7311	Differential nonlinearity			±0.2	±1	LSB
Offset error		Measured by the line passing through two codes[2]		±0.05	±4	mV
Offset error drift				3		µV/°C
Zero code error		All zeros loaded to the DAC register		0.2		mV
Full-scale error		All ones loaded to DAC register		0.04	0.2	% of FSR
Gain error				0.05	±0.15	% of FSR
Gain temperature coefficient		AV_{DD} = 5 V		±0.5		ppm of FSR/°C
Gain temperature coefficient		AV_{DD} = 2.0 V		±1.5		ppm of FSR/°C
OUTPUT CHARACTERISTICS						
Output voltage range			0		AV_{DD}	V
Output voltage settling time[3]		R_L = 2 kΩ, C_L = 200 pF, AV_{DD} = 5 V, 1/4 scale to 3/4 scale		6	10	µs
Output voltage settling time[3]		R_L = 2 MΩ, C_L = 470 pF		12		µs
Slew rate				0.7		V/µs
Capacitive load stability		R_L = ∞		470		pF
Capacitive load stability		R_L = 2 kΩ		1000		pF
Code change glitch impulse		1 LSB change around major carry		0.5		nV-s
Digital feedthrough				0.5		nV-s
Power-on glitch impulse		R_L = 2 kΩ, C_L = 200 pF, AV_{DD} = 5 V		17		mV
DC output impedance				0.5		Ω
Short circuit current		AV_{DD} = 5 V		50		mA
Short circuit current		AV_{DD} = 3 V		20		mA
Power-up time		Coming out of power-down mode		50		µs
AC PERFORMANCE						
SNR		T_A = 25°C, BW = 20 kHz, 12-bit level, AV_{DD} = 5 V, f_{OUT} = 1 kHz, 1st 19 harmonics removed for SNR calculation		81		dB
THD				–65		dB
SFDR				65		dB
SINAD				65		dB

7.5 Electrical Characteristics (continued)

at AV_{DD} = 2.0 V to 5.5 V, R_L = 2 kΩ to GND, C_L = 200 pF to GND, and T_A = –40°C to +125°C (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
DAC output noise density[4]		T_A = 25°C, at zero-scale input, f_{OUT} = 1 kHz, AV_{DD} = 5 V			17		nV/√Hz
		T_A = 25°C, at mid-code input, f_{OUT} = 1 kHz, AV_{DD} = 5 V			110		nV/√Hz
DAC output noise[5]		T_A= +25°C, at mid-code input, 0.1 Hz to 10 Hz, AV_{DD} = 5 V			3		μV_{PP}
LOGIC INPUTS[3]							
Input current						±1	µA
$V_{IN}L$, Input low voltage		AV_{DD} = 2.7 V to 5.5 V				0.3 × AV_{DD}	V
		AV_{DD} = 2.0 V to 2.7 V				0.1 × AV_{DD}	V
$V_{IN}H$, Input high voltage		AV_{DD} = 2.7 V to 5.5 V		0.7 × AV_{DD}			V
		AV_{DD} = 2.0 V to 2.7 V		0.9 × AV_{DD}			V
Pin capacitance					1.5	3	pF
POWER REQUIREMENTS							
AV_{DD}				2.0		5.5	V
I_{DD}	Normal mode	$V_{IN}H$ = AV_{DD} and $V_{IN}L$ = GND, at midscale code[6]	AV_{DD} = 3.6 V to 5.5 V		110	180	µA
			AV_{DD} = 2.7 V to 3.6 V		95	150	µA
			AV_{DD} = 2.0 V to 2.7 V		80	140	µA
	All power-down mode	$V_{IN}H$ = AV_{DD} and $V_{IN}L$ = GND, at midscale code[6]	AV_{DD} = 3.6 V to 5.5 V		0.5	3.5	µA
			AV_{DD} = 2.7 V to 3.6 V		0.4	3	µA
			AV_{DD} = 2.0 V to 2.7 V		0.1	2	µA
Power dissipation	Normal mode	$V_{IN}H$ = AV_{DD} and $V_{IN}L$ = GND, at midscale code[6]	AV_{DD} = 3.6 V to 5.5 V		0.55	0.99	mW
			AV_{DD} = 2.7 V to 3.6 V		0.25	0.54	mW
			AV_{DD} = 2.0 V to 2.7 V		0.14	0.38	mW
	All power-down mode	$V_{IN}H$ = AV_{DD} and $V_{IN}L$ = GND, at midscale code[6]	AV_{DD} = 3.6 V to 5.5 V		2.50	19.2	µW
			AV_{DD} = 2.7 V to 3.6 V		1.08	10.8	µW
			AV_{DD} = 2.0 V to 2.7 V		0.72	8.1	µW

(1) Linearity calculated using a reduced code range of 3 to 252 for 8-bit, 12 to 1012 for 10bit, and 30 to 4050 for 12-bit, output unloaded.
(2) Straight line passing through codes 3 and 252 for 8-bit, 12 and 1012 for 10-bit, and 30 and 4050 for 12-bit, output unloaded.
(3) Specified by design and characterization, not production tested.
(4) For more details, see Figure 7-23.
(5) For more details, see Figure 7-24.
(6) For more details, see Figure 7-16 and Figure 7-58.

7.6 Timing Requirements

at –40°C to 125°C, and AV_{DD} = 2 V to 5.5 V (unless otherwise noted)(1)

			MIN	NOM	MAX	UNIT
$f_{(SCLK)}$	Serial clock frequency	AV_{DD} = 2.0 V to 3.6 V			20	MHz
		AV_{DD} = 3.6 V to 5.5 V			50	
t_1	SCLK cycle time	AV_{DD} = 2.0 V to 3.6 V	50			ns
		AV_{DD} = 3.6 V to 5.5 V	20			
t_2	SCLK high time	AV_{DD} = 2.0 V to 3.6 V	25			ns
		AV_{DD} = 3.6 V to 5.5 V	10			
t_3	SCLK low time	AV_{DD} = 2.0 V to 3.6 V	25			ns
		AV_{DD} = 3.6 V to 5.5 V	10			
t_4	$\overline{\text{SYNC}}$ to SCLK rising edge setup time	AV_{DD} = 2.0 V to 3.6 V	0			ns
		AV_{DD} = 3.6 V to 5.5 V	0			
t_5	Data setup time	AV_{DD} = 2.0 V to 3.6 V	5			ns
		AV_{DD} = 3.6 V to 5.5 V	5			
t_6	Data hold time	AV_{DD} = 2.0 V to 3.6 V	4.5			ns
		AV_{DD} = 3.6 V to 5.5 V	4.5			
t_7	SCLK falling edge to $\overline{\text{SYNC}}$ rising edge	AV_{DD} = 2.0 V to 3.6 V	0			ns
		AV_{DD} = 3.6 V to 5.5 V	0			
t_8	Minimum $\overline{\text{SYNC}}$ high time	AV_{DD} = 2.0 V to 3.6 V	50			ns
		AV_{DD} = 3.6 V to 5.5 V	20			
t_9	16th SCLK falling edge to $\overline{\text{SYNC}}$ falling edge	AV_{DD} = 2.0 V to 3.6 V	100			ns
		AV_{DD} = 3.6 V to 5.5 V	100			
t_{10}	$\overline{\text{SYNC}}$ rising edge to 16th SCLK falling edge (for successful $\overline{\text{SYNC}}$ interrupt)	AV_{DD} = 2.0 V to 3.6 V	15			ns
		AV_{DD} = 3.6 V to 5.5 V	15			

(1) All input signals are specified with $t_R = t_F$ = 3 ns (10% to 90% of AV_{DD}) and timed from a voltage level of $(V_{IL} + V_{IH}) / 2$.

7.7 Timing Diagrams

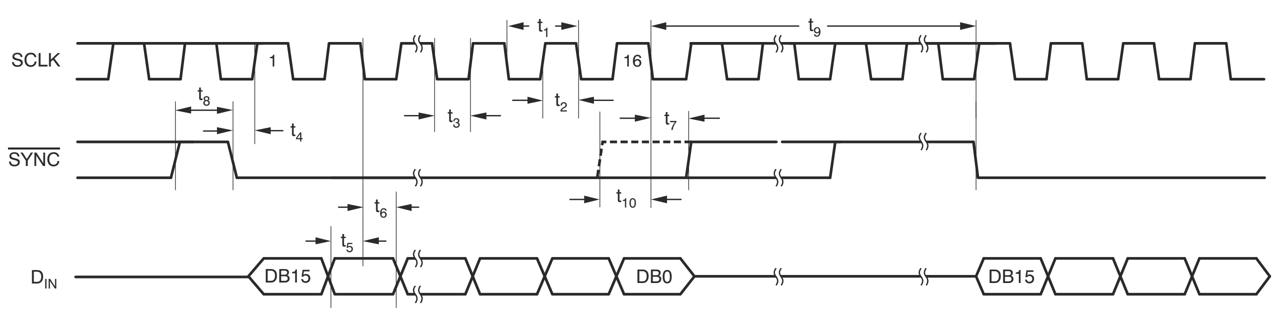


Figure 7-1. Serial Write Operation

7.8 Typical Characteristics: AV_{DD} = 5 V

at T_A = 25°C, AV_{DD} = 5 V, and DAC loaded with midscale code (unless otherwise noted)

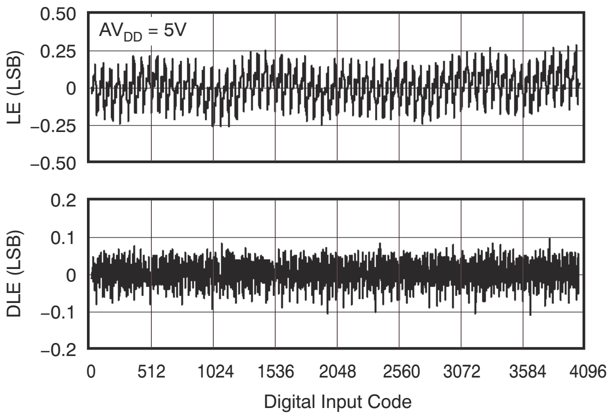


Figure 7-2. DAC7311 12-Bit Linearity Error and Differential Linearity Error vs Code (–40°C)

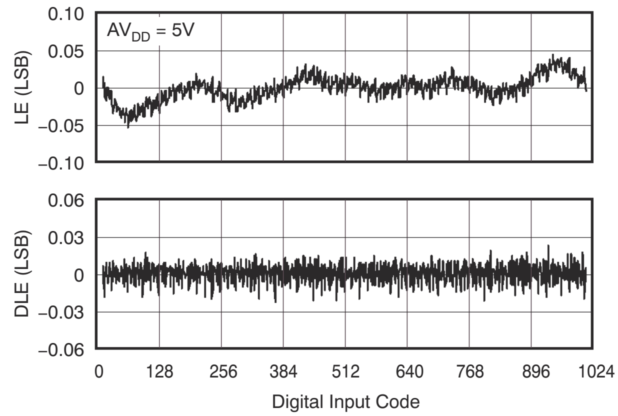


Figure 7-3. DAC6311 10-Bit Linearity Error and Differential Linearity Error vs Code (–40°C)

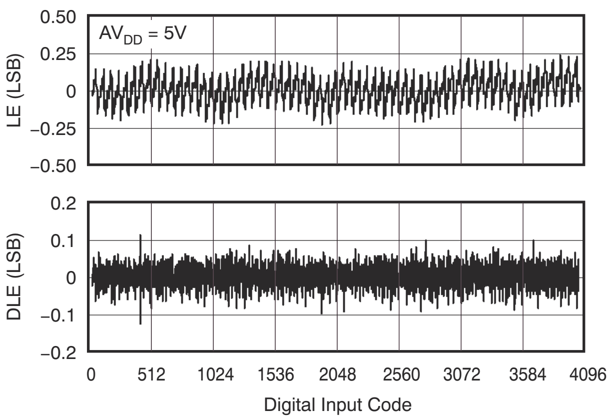


Figure 7-4. DAC7311 12-Bit Linearity Error and Differential Linearity Error vs Code (25°C)

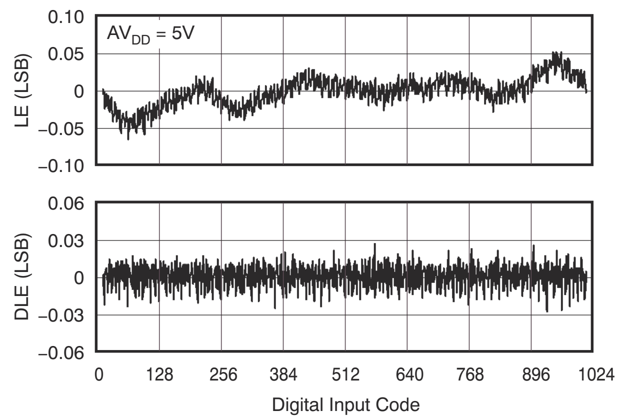


Figure 7-5. DAC6311 10-Bit Linearity Error and Differential Linearity Error vs Code (25°C)

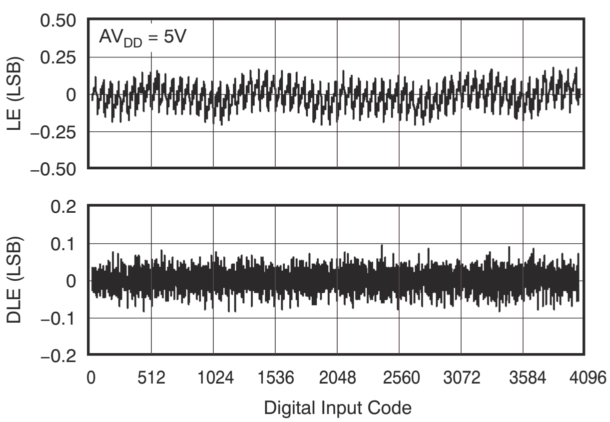


Figure 7-6. DAC7311 12-Bit Linearity Error and Differential Linearity Error vs Code (125°C)

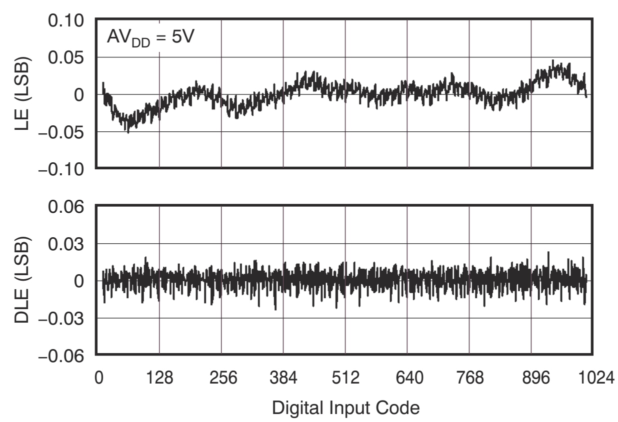


Figure 7-7. DAC6311 10-Bit Linearity Error and Differential Linearity Error vs Code (125°C)

7.8 Typical Characteristics: AV_{DD} = 5 V (continued)

at T_A = 25°C, AV_{DD} = 5 V, and DAC loaded with midscale code (unless otherwise noted)

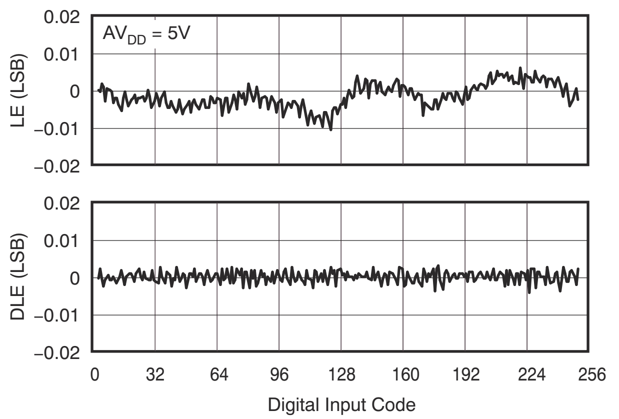


Figure 7-8. DAC5311 8-Bit Linearity Error and Differential Linearity Error vs Code (–40°C)

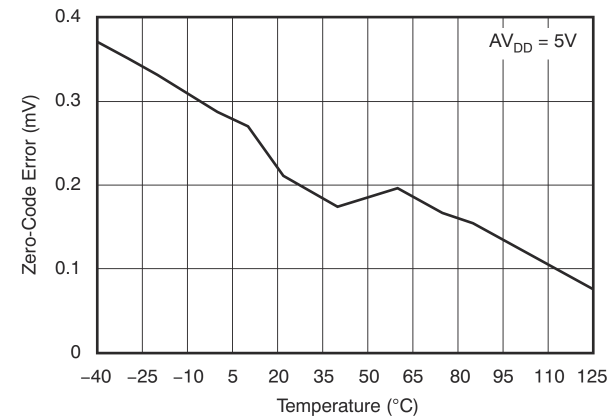


Figure 7-9. Zero-Code Error vs Temperature

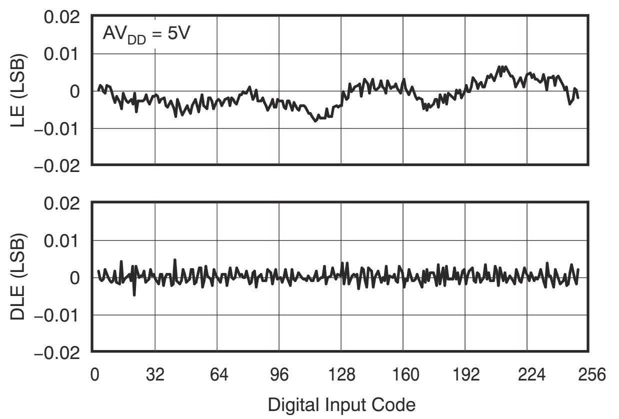


Figure 7-10. DAC5311 8-Bit Linearity Error and Differential Linearity Error vs Code (25°C)

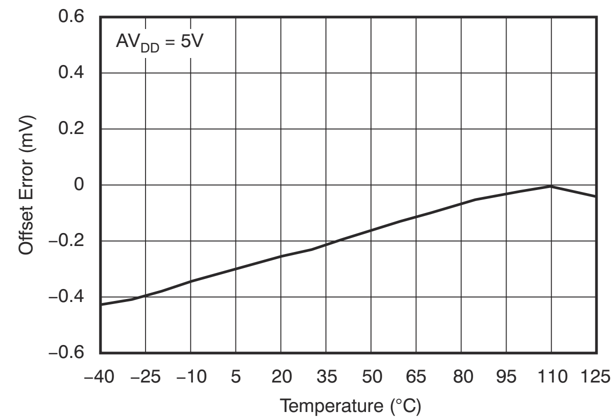


Figure 7-11. Offset Error vs Temperature

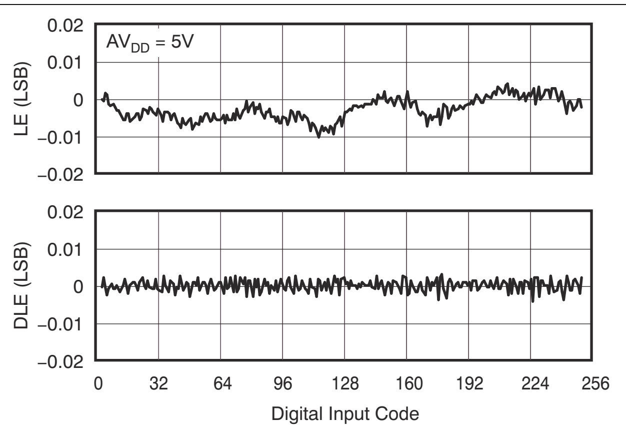


Figure 7-12. DAC5311 8-Bit Linearity Error and Differential Linearity Error vs Code (125°C)

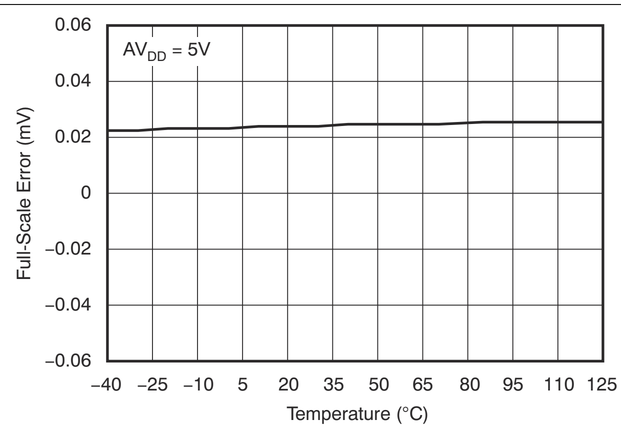


Figure 7-13. Full-Scale Error vs Temperature

7.8 Typical Characteristics: AV_{DD} = 5 V (continued)

at T_A = 25°C, AV_{DD} = 5 V, and DAC loaded with midscale code (unless otherwise noted)

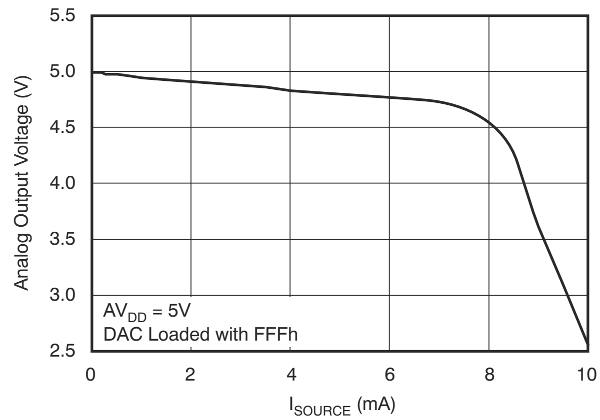


Figure 7-14. Source Current at Positive Rail

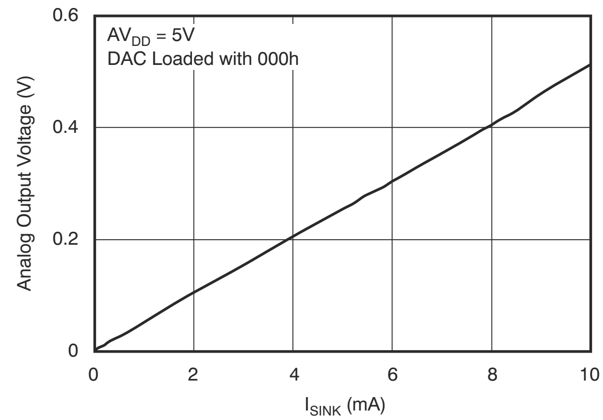


Figure 7-15. Sink Current at Negative Rail

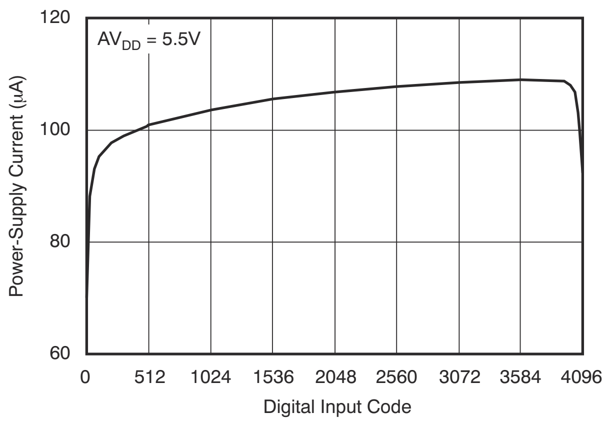


Figure 7-16. Power-Supply Current vs Digital Input Code

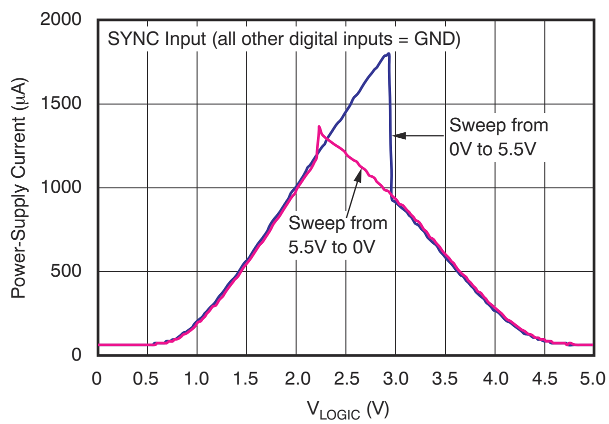


Figure 7-17. Power-Supply Current vs Logic Input Voltage

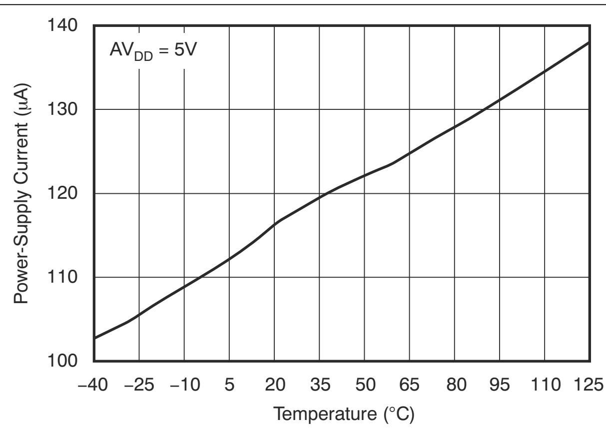


Figure 7-18. Power-Supply Current vs Temperature

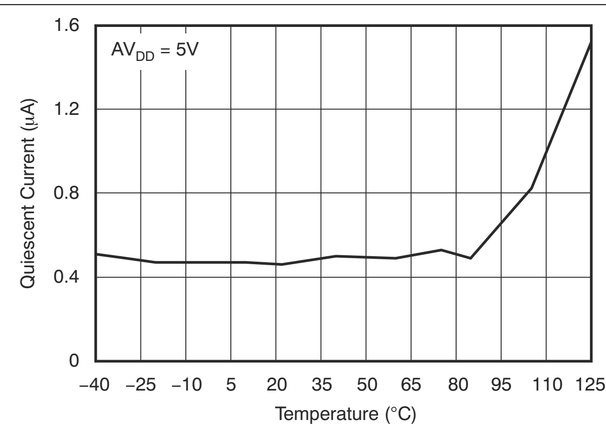


Figure 7-19. Power-Down Current vs Temperature

7.8 Typical Characteristics: AV_{DD} = 5 V (continued)

at T_A = 25°C, AV_{DD} = 5 V, and DAC loaded with midscale code (unless otherwise noted)

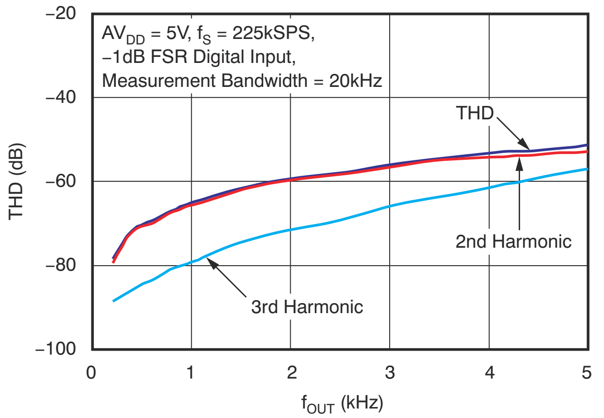


Figure 7-20. Total Harmonic Distortion vs Output Frequency

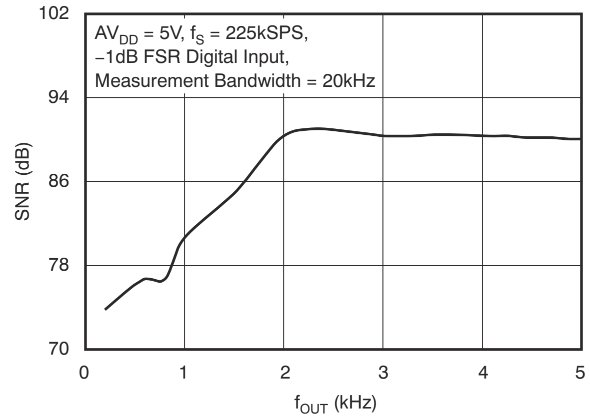


Figure 7-21. Signal-to-Noise Ratio vs Output Frequency

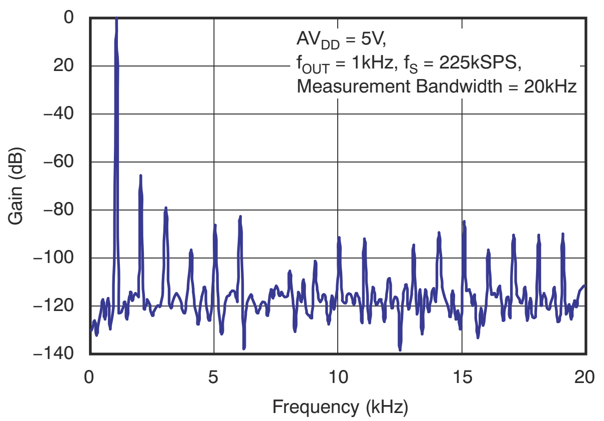


Figure 7-22. Power Spectral Density

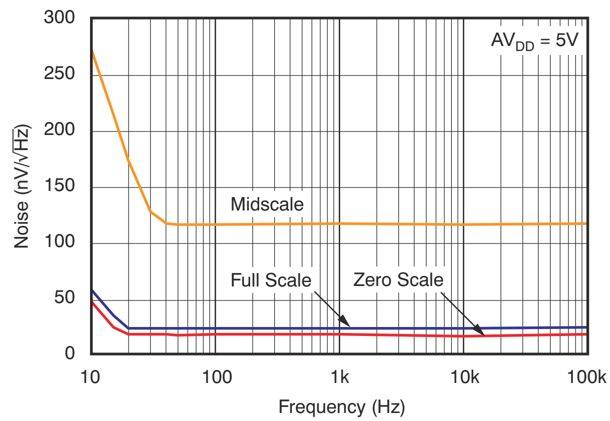


Figure 7-23. DAC Output Noise Density vs Frequency

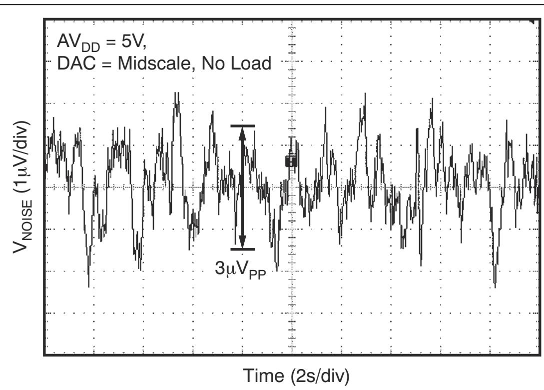


Figure 7-24. DAC Output Noise, 0.1-Hz to 10-Hz Bandwidth

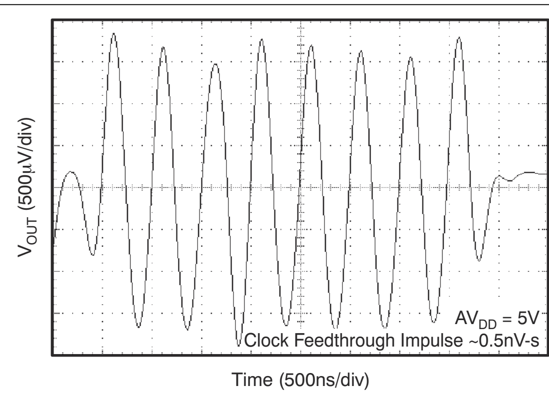


Figure 7-25. Clock Feedthrough, 5-V, 2-MHz, Midscale

7.8 Typical Characteristics: AV_{DD} = 5 V (continued)

at T_A = 25°C, AV_{DD} = 5 V, and DAC loaded with midscale code (unless otherwise noted)

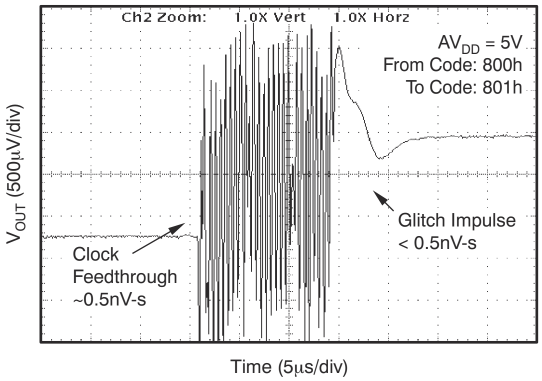


Figure 7-26. Glitch Energy, 5-V, 12-Bit, 1-LSB Step, Rising Edge

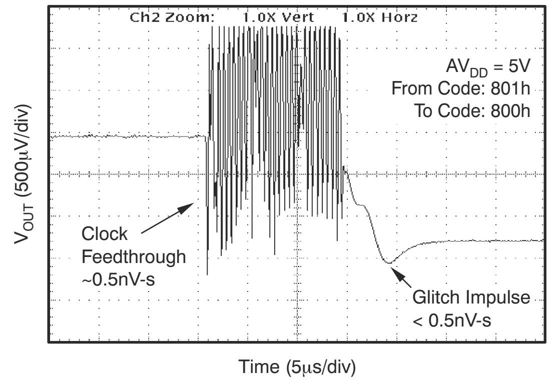


Figure 7-27. Glitch Energy, 5-V, 12-Bit, 1-LSB Step, Falling Edge

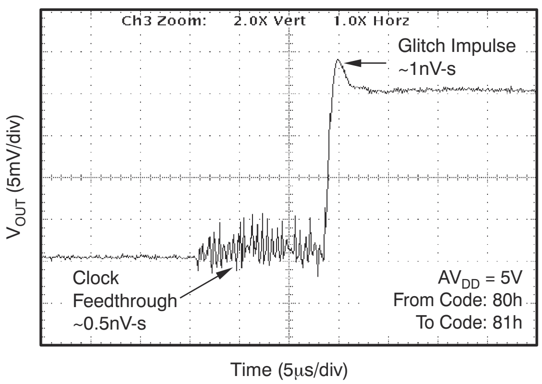


Figure 7-28. Glitch Energy, 5-V, 8-Bit, 1-LSB Step, Rising Edge

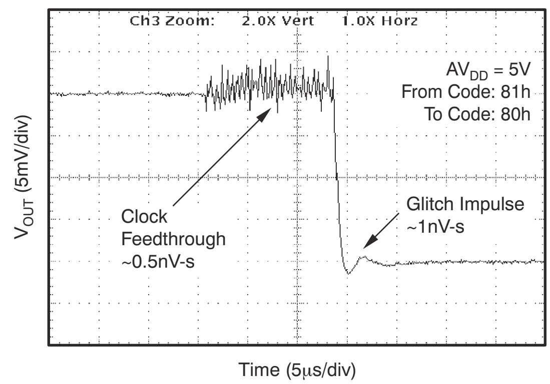


Figure 7-29. Glitch Energy, 5-V, 8-Bit, 1-LSB Step, Falling Edge

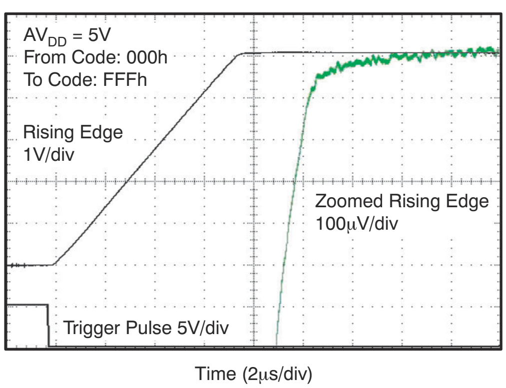


Figure 7-30. Full-Scale Settling Time, 5-V Rising Edge

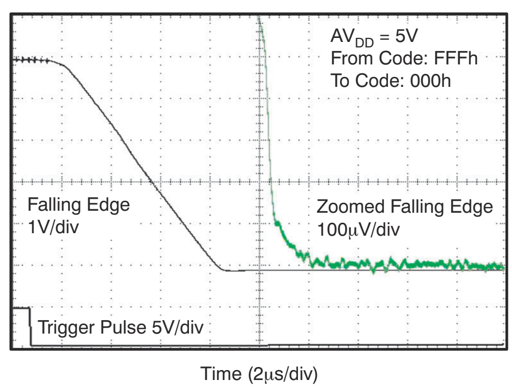


Figure 7-31. Full-Scale Settling Time, 5-V Falling Edge

7.8 Typical Characteristics: AV_{DD} = 5 V (continued)

at T_A = 25°C, AV_{DD} = 5 V, and DAC loaded with midscale code (unless otherwise noted)

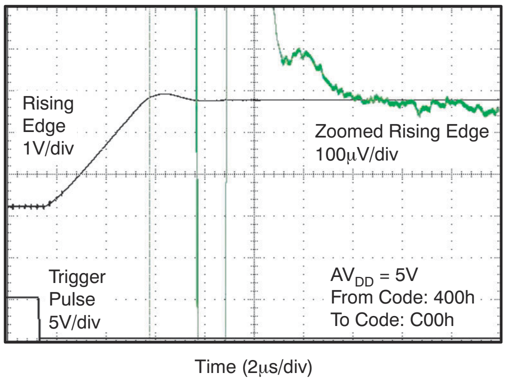


Figure 7-32. Half-Scale Settling Time, 5-V Rising Edge

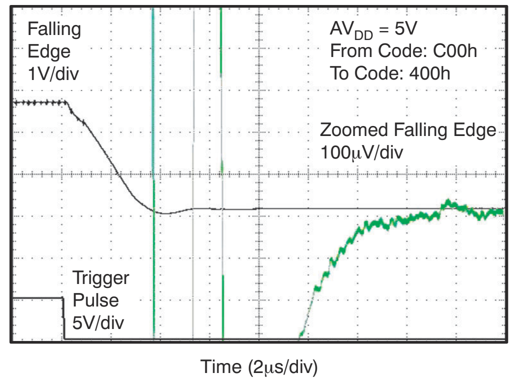


Figure 7-33. Half-Scale Settling Time 5-V Falling Edge

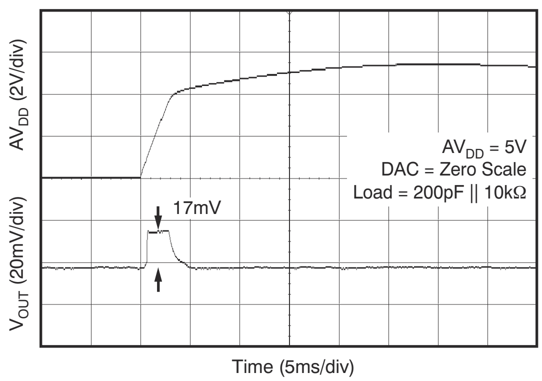


Figure 7-34. Power-On Reset to 0-V Power-On Glitch

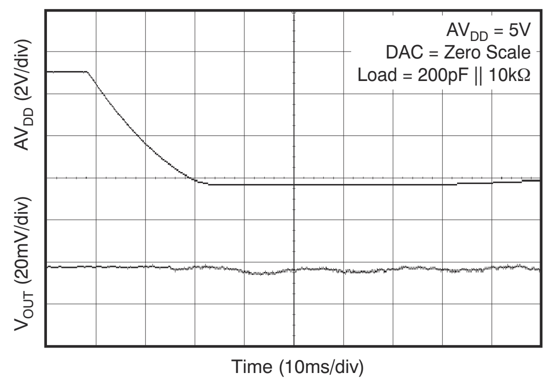


Figure 7-35. Power-Off Glitch

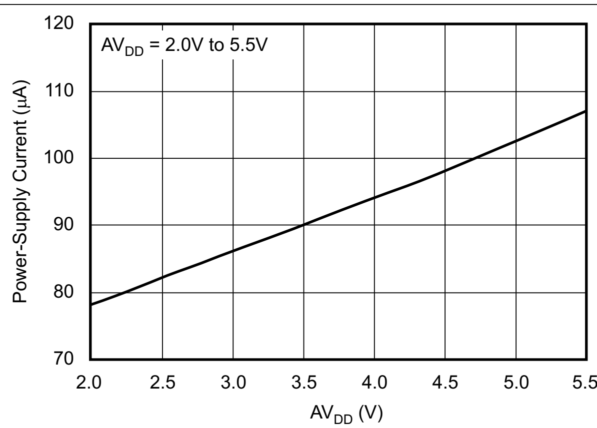


Figure 7-36. Power-Supply Current vs Power-Supply Voltage

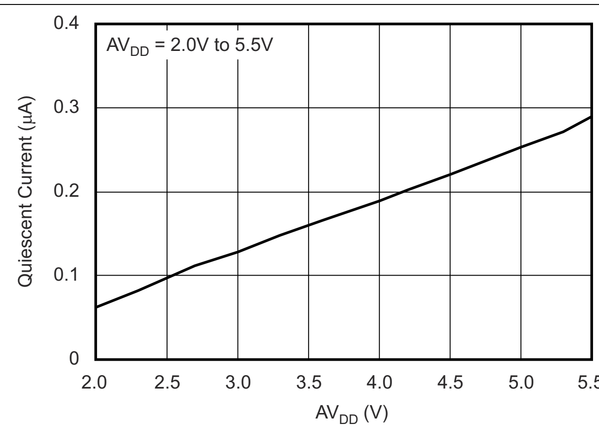


Figure 7-37. Power-Down Current vs Power-Supply Voltage

7.8 Typical Characteristics: AV_{DD} = 5 V (continued)

at T_A = 25°C, AV_{DD} = 5 V, and DAC loaded with midscale code (unless otherwise noted)

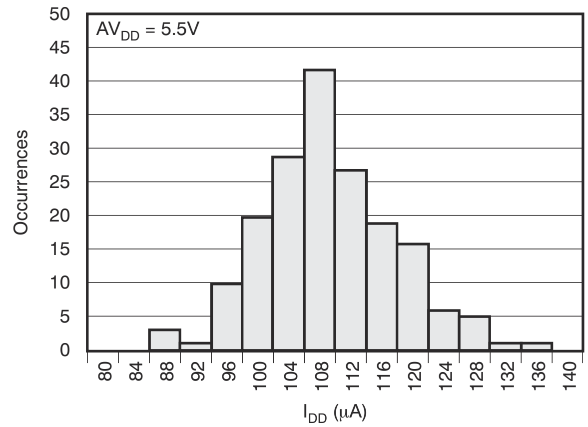


Figure 7-38. Power-Supply Current Histogram

7.9 Typical Characteristics: AV_{DD} = 3.6 V

at T_A = 25°C, AV_{DD} = 3.6 V, and DAC loaded with midscale code (unless otherwise noted)

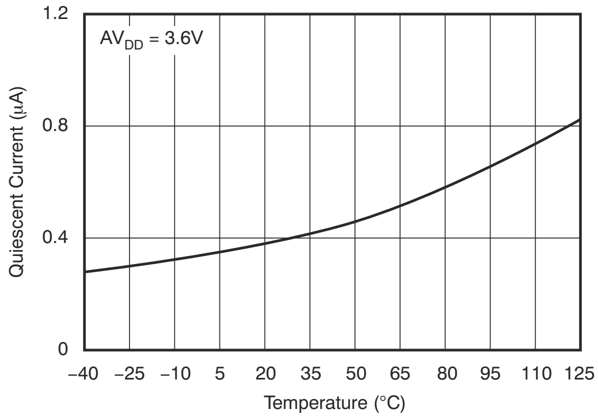


Figure 7-39. Power-Down Current vs Temperature

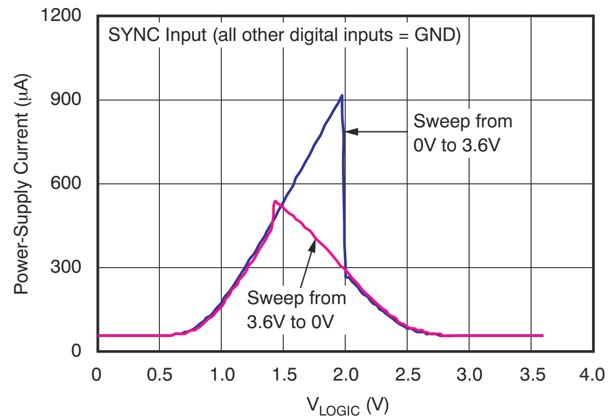


Figure 7-40. Power-Supply Current vs Logic Input Voltage

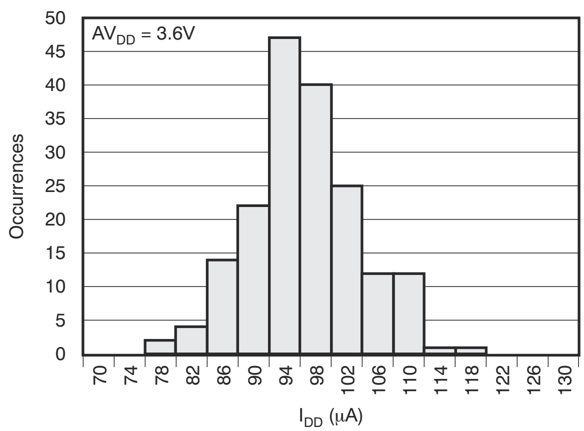


Figure 7-41. Power-Supply Current Histogram

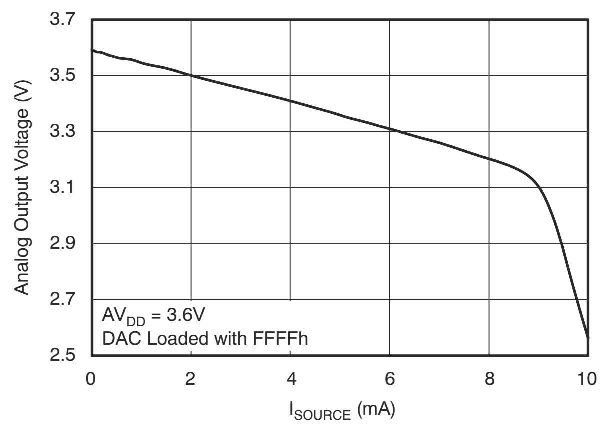


Figure 7-42. Source Current at Positive Rail

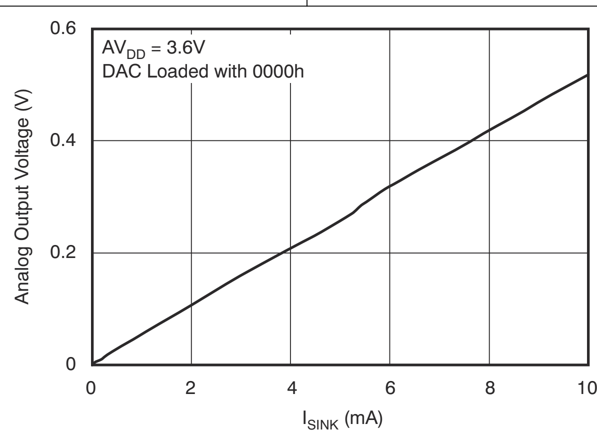


Figure 7-43. Sink Current at Negative Rail

7.10 Typical Characteristics: AV_{DD} = 2.7 V

at T_A = 25°C, AV_{DD} = 2.7 V, and DAC loaded with midscale code (unless otherwise noted)

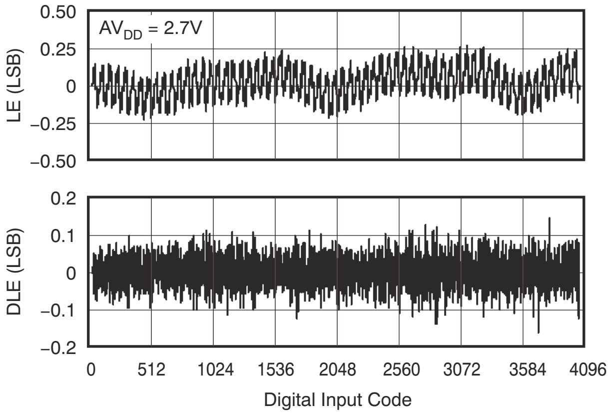


Figure 7-44. DAC7311 12-Bit Linearity Error and Differential Linearity Error vs Code (–40°C)

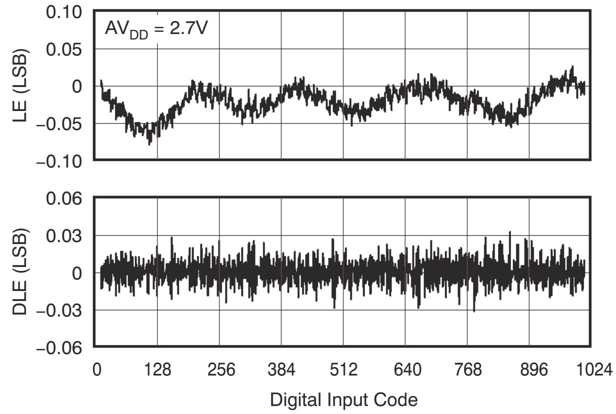


Figure 7-45. DAC6311 10-Bit Linearity Error and Differential Linearity Error vs Code (–40°C)

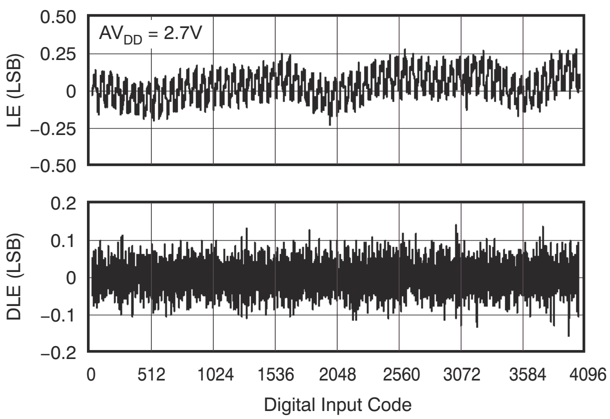


Figure 7-46. DAC7311 12-Bit Linearity Error and Differential Linearity Error vs Code (25°C)

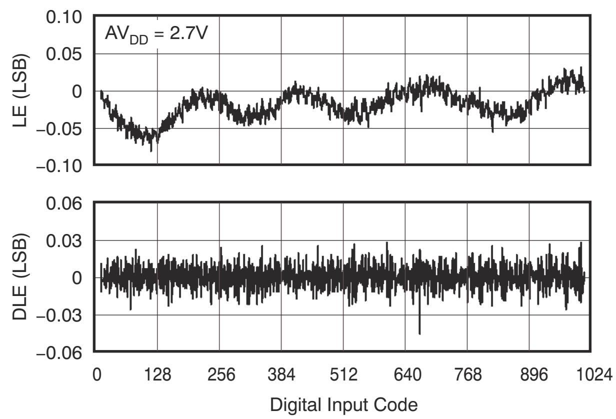


Figure 7-47. DAC6311 10-Bit Linearity Error and Differential Linearity Error vs Code (25°C)

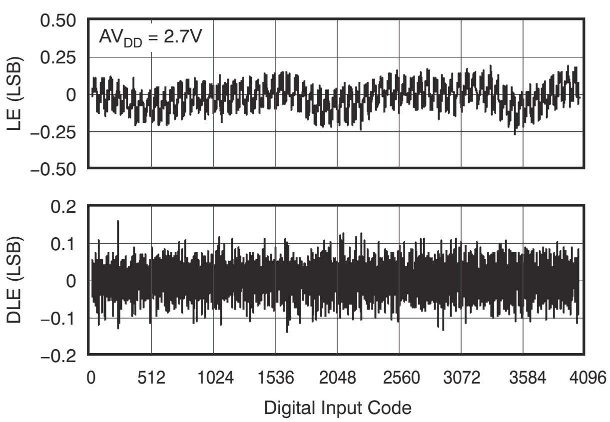


Figure 7-48. DAC7311 12-Bit Linearity Error and Differential Linearity Error vs Code (125°C)

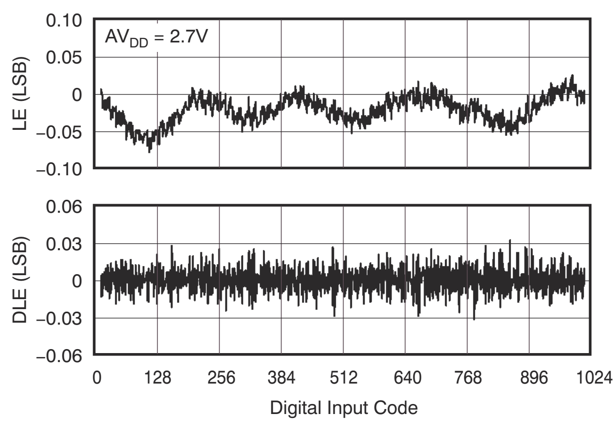


Figure 7-49. DAC6311 10-Bit Linearity Error and Differential Linearity Error vs Code (125°C)

7.10 Typical Characteristics: AV_{DD} = 2.7 V (continued)

at T_A = 25°C, AV_{DD} = 2.7 V, and DAC loaded with midscale code (unless otherwise noted)

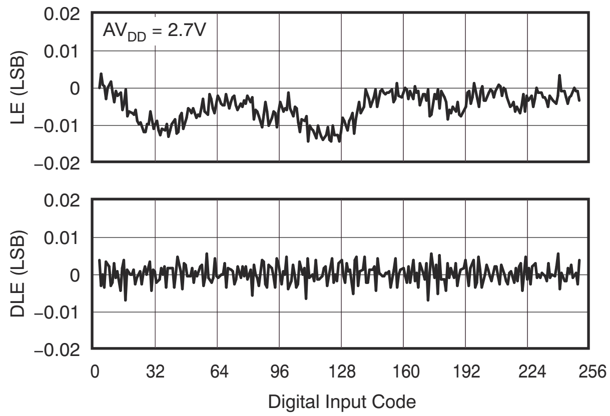


Figure 7-50. DAC5311 8-Bit Linearity Error and Differential Linearity Error vs Code (–40°C)

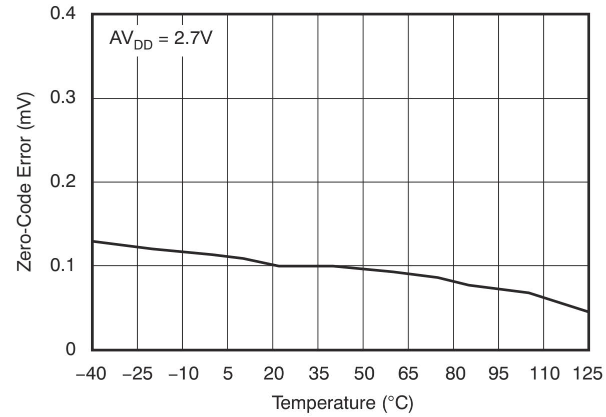


Figure 7-51. Zero-Code Error vs Temperature

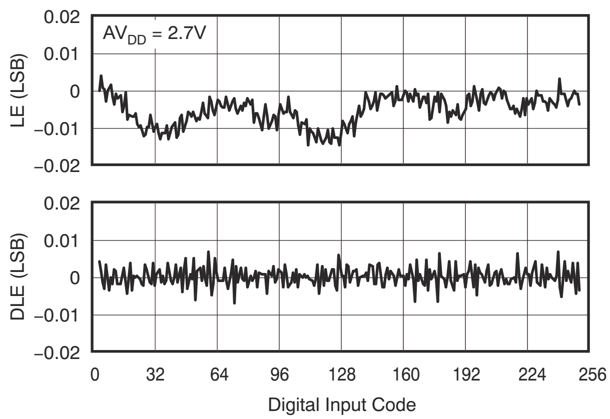


Figure 7-52. DAC5311 8-Bit Linearity Error and Differential Linearity Error vs Code (25°C)

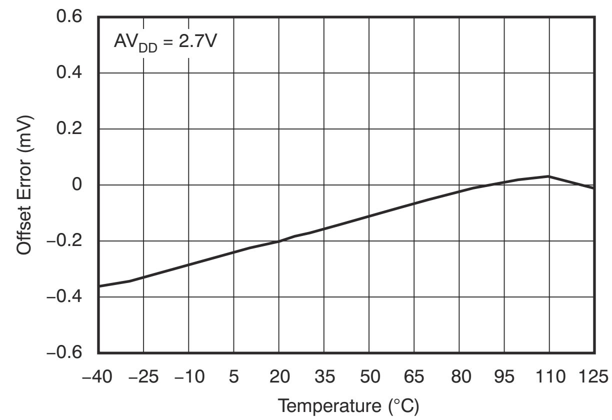


Figure 7-53. Offset Error vs Temperature

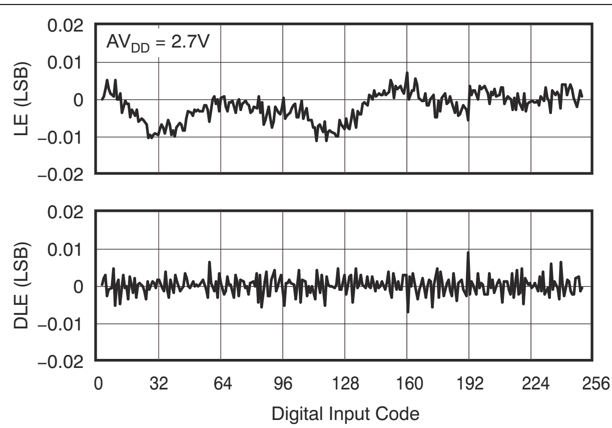


Figure 7-54. DAC5311 8-Bit Linearity Error and Differential Linearity Error vs Code (125°C)

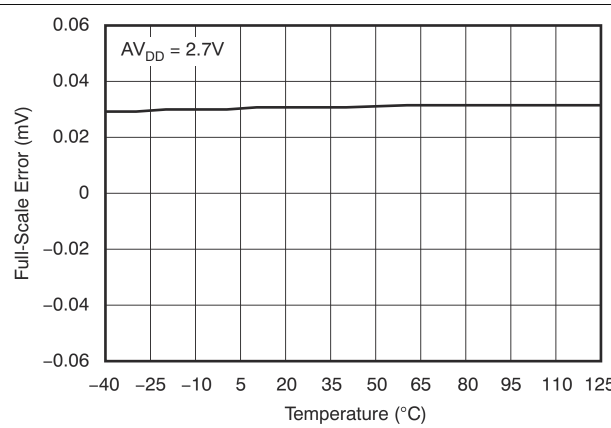


Figure 7-55. Full-Scale Error vs Temperature

7.10 Typical Characteristics: AV_{DD} = 2.7 V (continued)

at T_A = 25°C, AV_{DD} = 2.7 V, and DAC loaded with midscale code (unless otherwise noted)

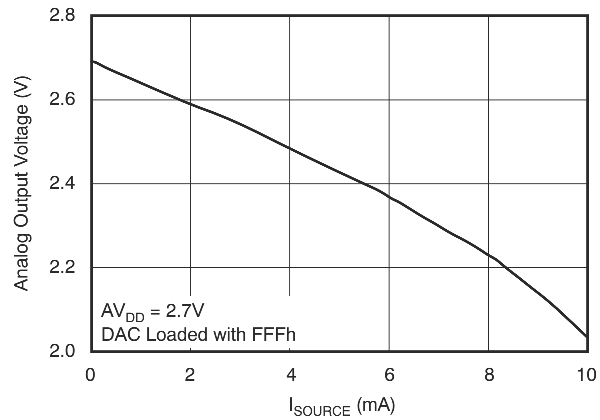


Figure 7-56. Source Current at Positive Rail

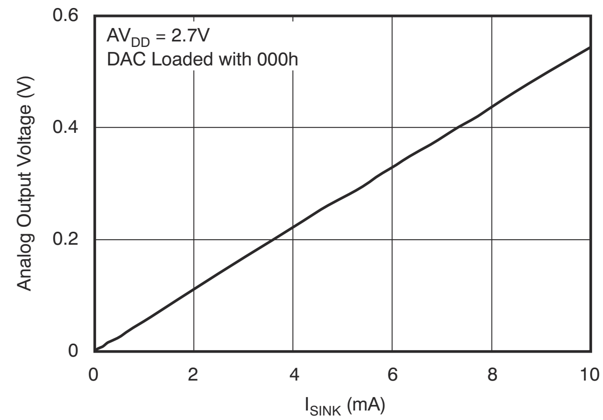


Figure 7-57. Sink Current at Negative Rail

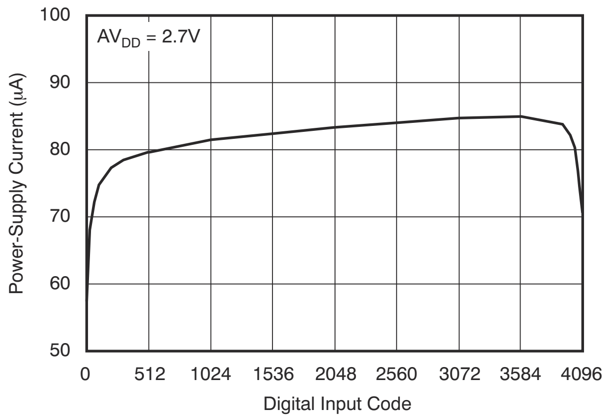


Figure 7-58. Power-Supply Current vs Digital Input Code

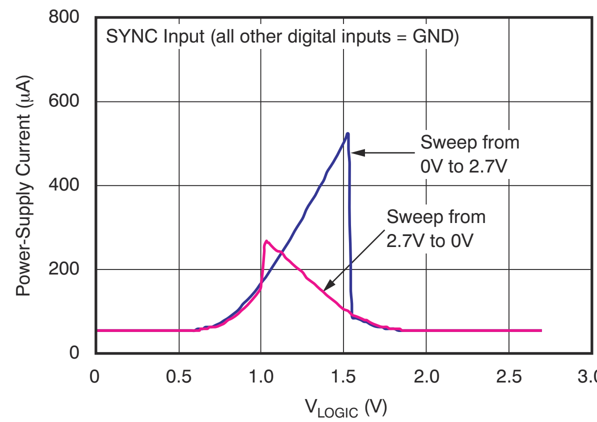


Figure 7-59. Power-Supply Current vs Logic Input Voltage

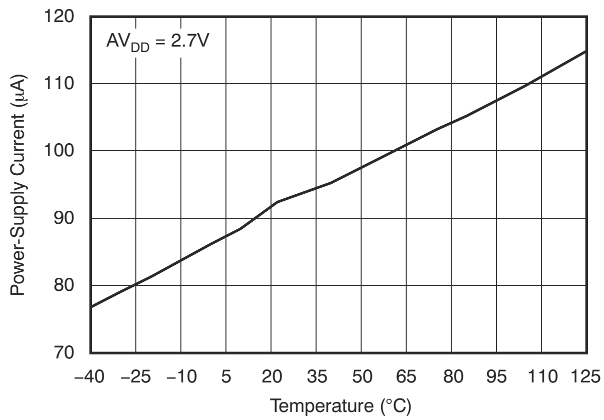


Figure 7-60. Power-Supply Current vs Temperature

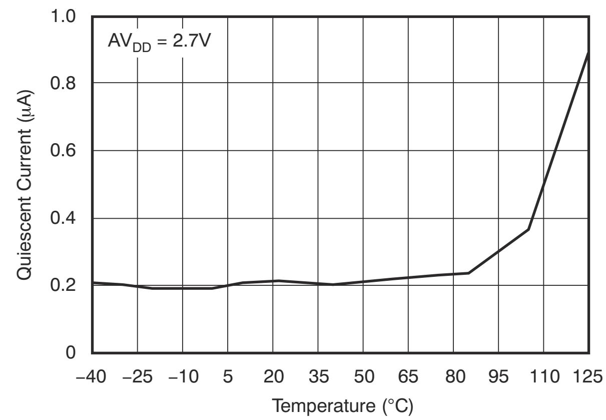


Figure 7-61. Power-Down Current vs Temperature

7.10 Typical Characteristics: AV_{DD} = 2.7 V (continued)

at T_A = 25°C, AV_{DD} = 2.7 V, and DAC loaded with midscale code (unless otherwise noted)

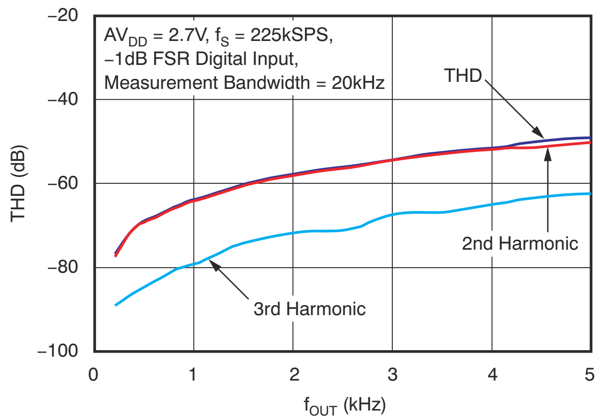


Figure 7-62. Total Harmonic Distortion vs Output Frequency

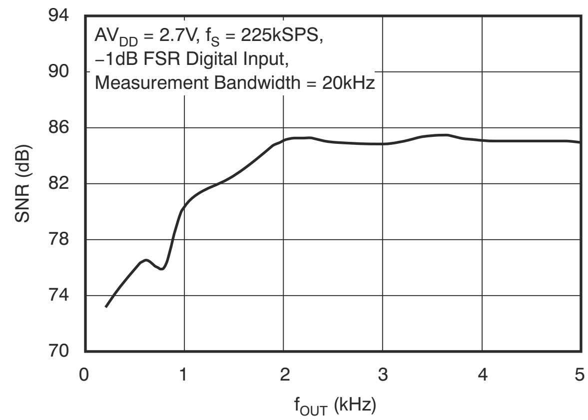


Figure 7-63. Signal-to-Noise Ratio vs Output Frequency

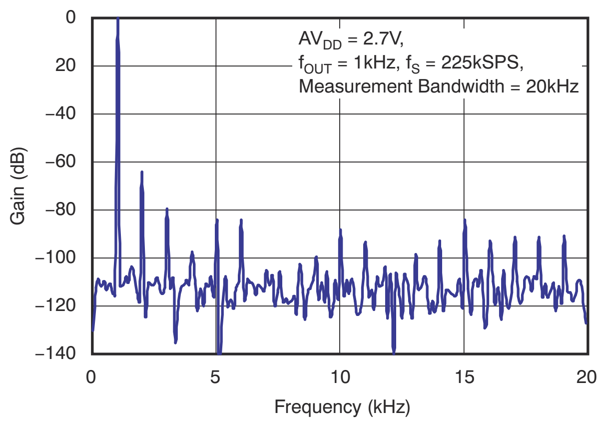


Figure 7-64. Power Spectral Density

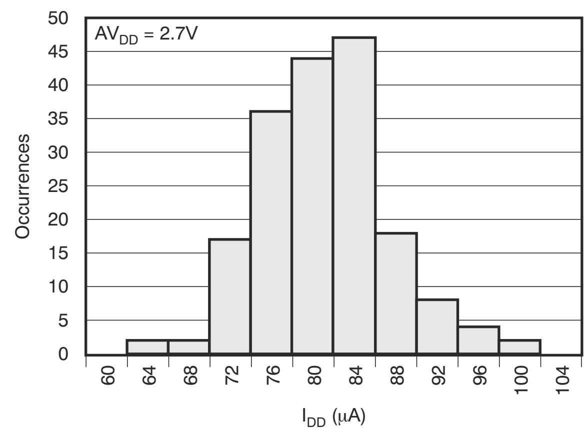


Figure 7-65. Power-Supply Current Histogram

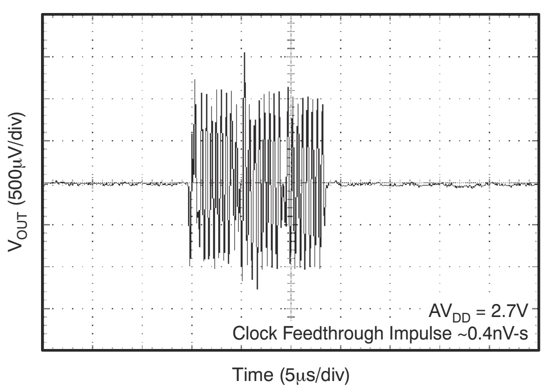


Figure 7-66. Clock Feedthrough 2.7-V, 20-MHz, Midscale

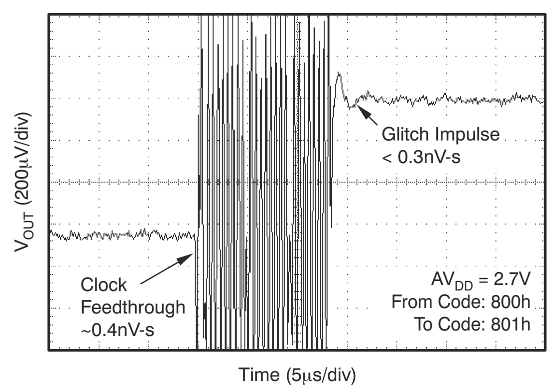


Figure 7-67. Glitch Energy, 2.7-V, 12-Bit, 1-LSB Step, Rising Edge

7.10 Typical Characteristics: AV_{DD} = 2.7 V (continued)

at T_A = 25°C, AV_{DD} = 2.7 V, and DAC loaded with midscale code (unless otherwise noted)

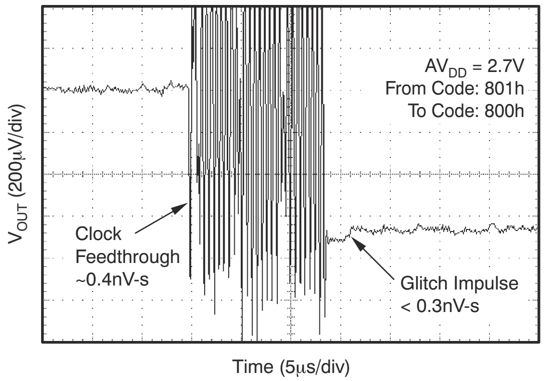


Figure 7-68. Glitch Energy, 2.7-V, 12-Bit, 1-LSB Step, Falling Edge

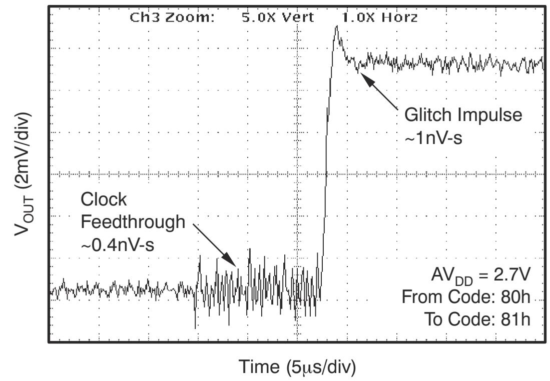


Figure 7-69. Glitch Energy, 2.7-V, 8-Bit, 1-LSB Step, Rising Edge

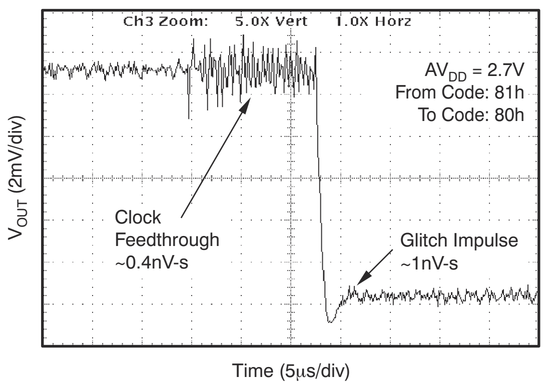


Figure 7-70. Glitch Energy, 2.7-V, 8-Bit, 1-LSB Step, Falling Edge

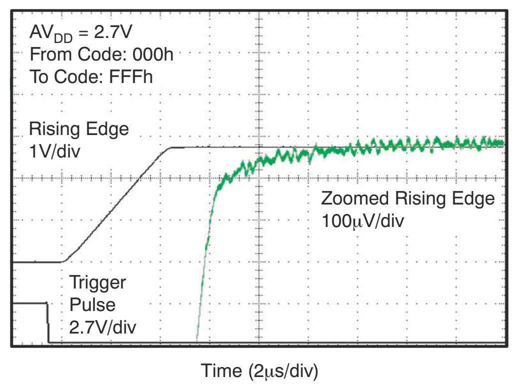


Figure 7-71. Full-Scale Settling Time, 2.7-V Rising Edge

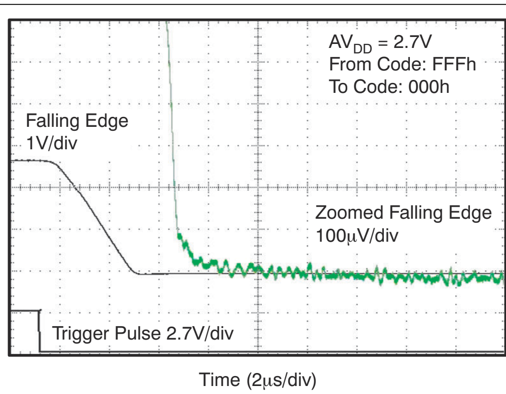


Figure 7-72. Full-Scale Settling Time, 2.7-V Falling Edge

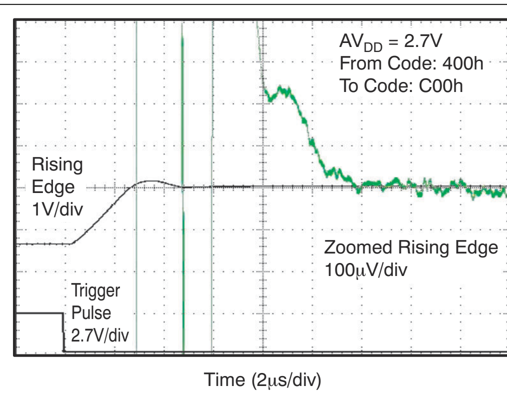


Figure 7-73. Half-Scale Settling Time, 2.7-V Rising Edge

7.10 Typical Characteristics: AV_{DD} = 2.7 V (continued)

at T_A = 25°C, AV_{DD} = 2.7 V, and DAC loaded with midscale code (unless otherwise noted)

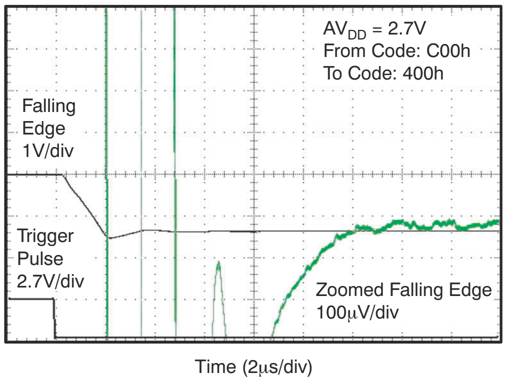


Figure 7-74. Half-Scale Settling Time, 2.7-V Falling Edge

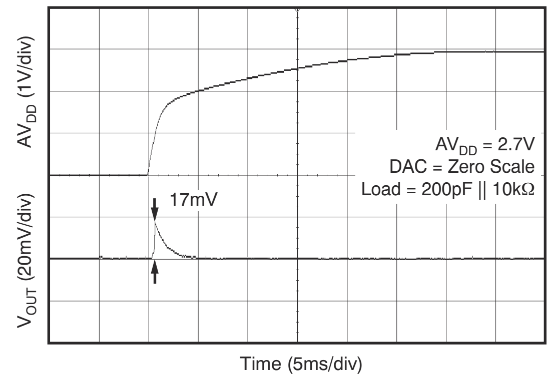


Figure 7-75. Power-On Reset to 0-V Power-On Glitch

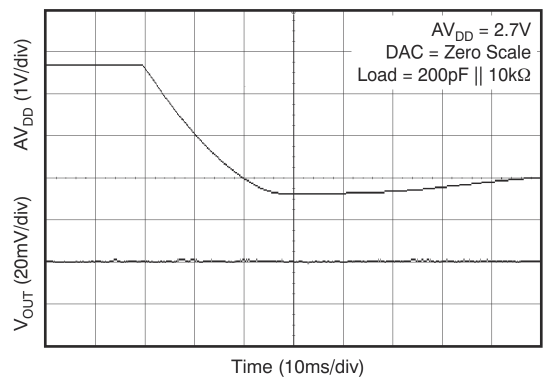


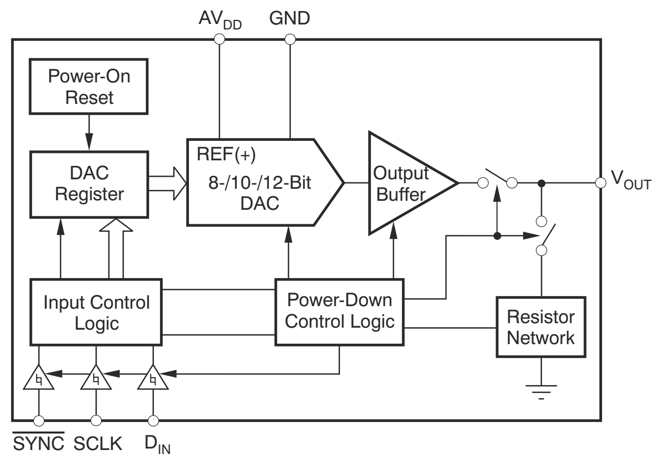
Figure 7-76. Power-Off Glitch

8 Detailed Description

8.1 Overview

The 8-bit DAC5311, 10-bit DAC6311, and 12-bit DAC7311 devices (DACx311) are low-power, single-channel, voltage output DACs. These devices are monotonic by design, provide excellent linearity, and minimize undesired code-to-code transient voltages while offering an easy upgrade path within a pin-compatible family. All devices use a versatile, three-wire serial interface that operates at clock rates of up to 50 MHz and is compatible with standard SPI, QSPI, Microwire, and digital signal processor (DSP) interfaces.

8.2 Functional Block Diagram



8.3 Feature Description

8.3.1 DAC Section

The DACx311 are fabricated using Texas Instruments' proprietary HPA07 process technology. The architecture consists of a string DAC followed by an output buffer amplifier. Because there is no reference input pin, the power supply (AV_{DD}) acts as the reference. Figure 8-1 shows a block diagram of the DAC architecture.

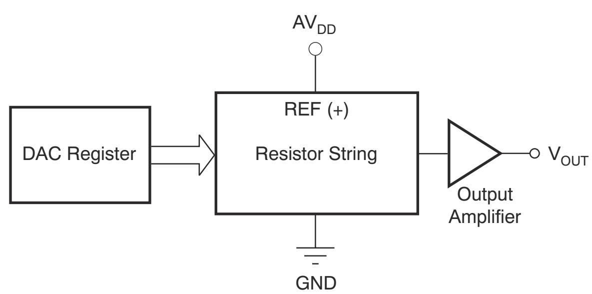


Figure 8-1. DACx311 Architecture

The input coding to the DACx311 is straight binary, so the ideal output voltage is given by:

$$V_{OUT} = AV_{DD} \times \frac{D}{2^n} \tag{1}$$

where

- n = resolution in bits; either 8 (DAC5311), 10 (DAC6311), or 12 (DAC7311).
- D = decimal equivalent of the binary code that is loaded to the DAC register. D ranges from 0 to 255 for 8-bit DAC5311, 0 to 1023 for the 10-bit DAC6311, and 0 to 4095 for the 12-bit DAC7311.

8.3.2 Resistor String

Figure 8-2 shows the resistor string section, which is a string of resistors, each of value R. The code loaded into the DAC register determines at which node on the string the voltage is tapped off to be fed into the output amplifier by closing one of the switches connecting the string to the amplifier. The resistor string architecture is inherently monotonic.

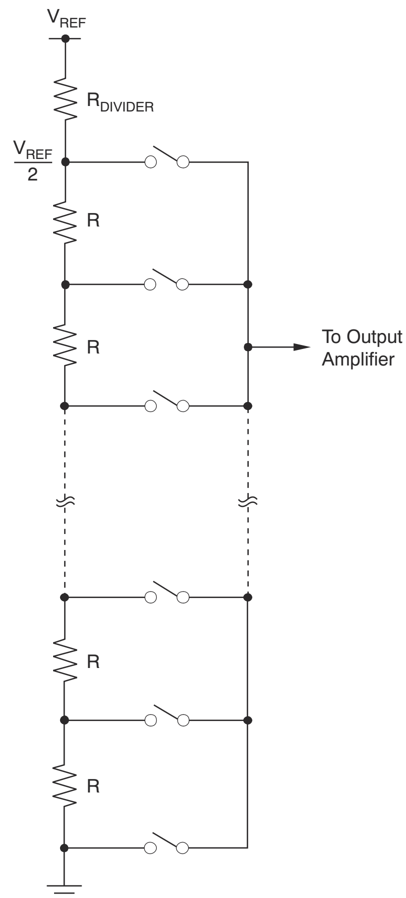


Figure 8-2. Resistor String

8.3.3 Output Amplifier

The output buffer amplifier is capable of generating rail-to-rail voltages on the output, which gives an output range of 0 V to AV_{DD}. The output amplifier is capable of driving a load of 2 kΩ in parallel with 1000 pF to GND. The source and sink capabilities of the output amplifier can be seen in the *Typical Characteristics* section for the given voltage input. The slew rate is 0.7 V/µs with a half-scale settling time of typically 6 µs with the output unloaded.

8.3.4 Power-On Reset

The DACx311 contain a power-on reset circuit that controls the output voltage during power up. On power up, the DAC register is filled with zeros and the output voltage is 0 V. The DAC register remains that way until a valid write sequence is made to the DAC. This design is useful in applications where knowing the state of the DAC output while powering up is important.

The occurring power-on glitch impulse is only a few millivolts (typically, 17 mV; see Figure 7-34).

8.4 Device Functional Modes

8.4.1 Power-Down Modes

The DACx311 contain four separate modes of operation. These modes are programmable by setting two bits (PD1 and PD0) in the control register. Table 8-1 shows how the state of the bits corresponds to the mode of operation of the device.

Table 8-1. Modes of Operation for the DACx311

PD1	PD0	OPERATING MODE
NORMAL MODE		
0	0	Normal Operation
POWER-DOWN MODES		
0	1	Output 1 kΩ to GND
1	0	Output 100 kΩ to GND
1	1	High-Z

When both bits are set to 0, the device works normally with a standard power consumption of typically 80 µA at 2 V. However, for the three power-down modes, the typical supply current falls to 0.5 µA at 5 V, 0.4 µA at 3 V, and 0.1 µA at 2 V. Not only does the supply current fall, but the output stage is also internally switched from the output of the amplifier to a resistor network of known values. The advantage of this architecture is that the output impedance of the part is known while the part is in power-down mode. There are three different options: the output is connected internally to GND either through a 1-kΩ resistor or a 100-kΩ resistor, or is left open-circuited (High-Z). Figure 8-3 illustrates the output stage.

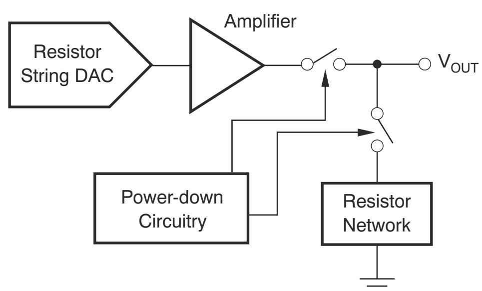


Figure 8-3. Output Stage During Power-Down

All linear circuitry is shut down when the power-down mode is activated. However, the contents of the DAC register are unaffected when in power-down. The time to exit power-down is typically 50 µs for AV_{DD} = 5 V and AV_{DD} = 3 V.

8.5 Programming

8.5.1 Serial Interface

The DACx311 has a 3-wire serial interface ($\overline{\text{SYNC}}$, SCLK, and DIN) compatible with SPI, QSPI, and Microwire interface standards, as well as most DSPs. For an example of a typical write sequence, see Figure 7-1.

8.5.1.1 Input Shift Register

The input shift register is 16 bits wide, as shown in Table 8-2. The first two bits (PD0 and PD1) are reserved control bits that set the desired mode of operation (normal mode or any one of three power-down modes) as indicated in Table 8-1.

The remaining data bits are either 12 (DAC7311), 10 (DAC6311), or 8 (DAC5311) data bits, followed by *don't care* bits, as shown in Table 8-2, Table 8-3, and Table 8-4, respectively.

Table 8-2. DAC5311 8-Bit Data Input Register

DB15	DB14								DB6	DB5					DB0
PD1	PD0	D7	D6	D5	D4	D3	D2	D1	D0	X	X	X	X	X	X

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

Table 8-3. DAC6311 10-Bit Data Input Register

DB15	DB14										DB4	DB3			DB0
PD1	PD0	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0	X	X	X	X

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

Table 8-4. DAC7311 12-Bit Data Input Register

DB15	DB14												DB2	DB1	DB0
PD1	PD0	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0	X	X

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

The write sequence begins by bringing the $\overline{\text{SYNC}}$ line low. Data from the DIN line are clocked into the 16-bit shift register on each falling edge of SCLK. The serial clock frequency can be as high as 50 MHz, making

the DACx311 compatible with high-speed DSPs. On the 16th falling edge of the serial clock, the last data bit is clocked in and the programmed function is executed.

At this point, the $\overline{\text{SYNC}}$ line can be kept low or brought high. In either case, $\overline{\text{SYNC}}$ must be brought high for a minimum of 20 ns before the next write sequence so that a falling edge of $\overline{\text{SYNC}}$ can initiate the next write sequence.

8.5.1.2 $\overline{\text{SYNC}}$ Interrupt

In a normal write sequence, the $\overline{\text{SYNC}}$ line is kept low for at least 16 falling edges of SCLK and the DAC is updated on the 16th falling edge. However, bringing $\overline{\text{SYNC}}$ high before the 16th falling edge acts as an interrupt to the write sequence. The shift register is reset and the write sequence is seen as invalid. Neither an update of the DAC register contents nor a change in the operating mode occurs, as shown in Figure 8-4.

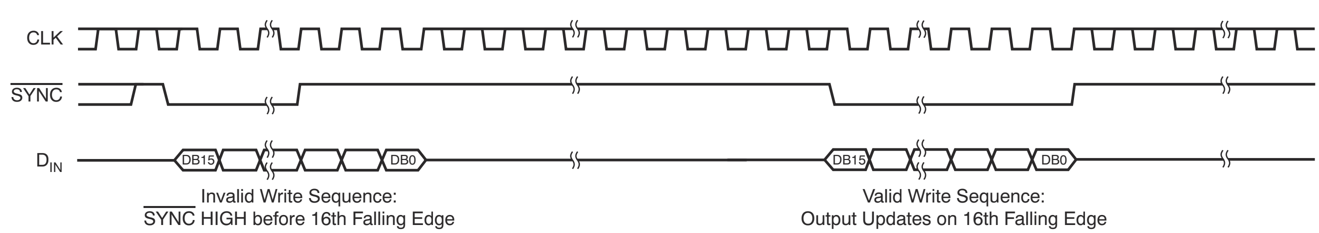


Figure 8-4. DACx311 $\overline{\text{SYNC}}$ Interrupt Facility

9 Application and Implementation

Note

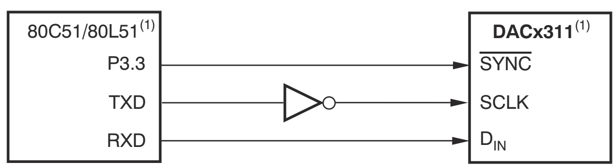
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

9.1 Application Information

9.1.1 Microprocessor Interfacing

9.1.1.1 DACx311 to 8051 Interface

Figure 9-1 shows a serial interface between the DACx311 and a typical 8051-type microcontroller. The setup for the interface is as follows: TXD of the 8051 drives SCLK of the DACx311, while RXD drives the serial data line of the device. The SYNC signal is derived from a bit programmable pin on the port. In this case, port line P3.3 is used. When data are to be transmitted to the DACx311, P3.3 is taken low. The 8051 transmits data only in 8-bit bytes; thus, only eight falling clock edges occur in the transmit cycle. To load data to the DAC, P3.3 remains low after the first eight bits are transmitted, and a second write cycle is initiated to transmit the second byte of data. P3.3 is taken high following the completion of this cycle. The 8051 outputs the serial data in a format that has the LSB first. The DACx311 requires data with the MSB as the first bit received. Therefore, the 8051 transmit routine must take this requirement into account, and *mirror* the data as needed.

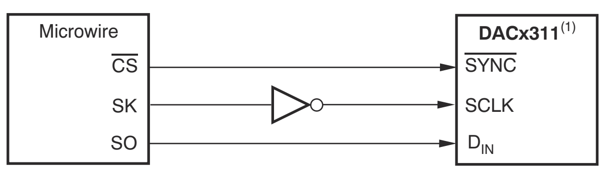


NOTE: (1) Additional pins omitted for clarity.

Figure 9-1. DACx311 to 80C51/80I51 Interfaces

9.1.1.2 DACx311 to Microwire Interface

Figure 9-2 shows an interface between the DACx311 and any Microwire-compatible device. Serial data (SO) are shifted out on the falling edge of the serial clock (SK) and are clocked into the DACx311 on the rising edge of the SK signal.



NOTE: (1) Additional pins omitted for clarity.

Figure 9-2. DACx311 to Microwire Interface

9.1.1.3 DACx311 to 68HC11 Interface

Figure 9-3 shows a serial interface between the DACx311 and the 68HC11 microcontroller. SCK of the 68HC11 drives the SCLK of the DACx311, while the MOSI output drives the serial data line of the DAC. The $\overline{SYNC}$ signal is derived from a port line (PC7), similar to what was done for the 8051.

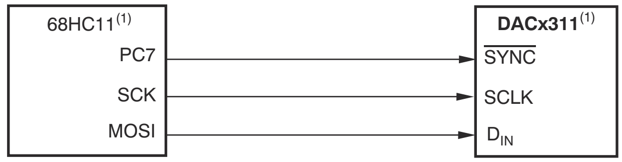


Figure 9-3. DACx311 to 68HC11 Interface

Configure the 68HC11 so that the CPOL bit is 0 and the CPHA bit is 1. This configuration causes data appearing on the MOSI output to be valid on the falling edge of SCK. When data are being transmitted to the DAC, the $\overline{SYNC}$ line is taken low (PC7). Serial data from the 68HC11 are transmitted in 8-bit bytes with only eight falling clock edges occurring in the transmit cycle. Data are transmitted MSB first. To load data to the DACx311, PC7 is held low after the first eight bits are transferred, and a second serial write operation is performed to the DAC; PC7 is taken high at the end of this procedure.

9.2 Typical Applications

9.2.1 Loop Powered Transmitter

The described loop powered transmitter can accurately source currents from 4 mA to 20 mA.

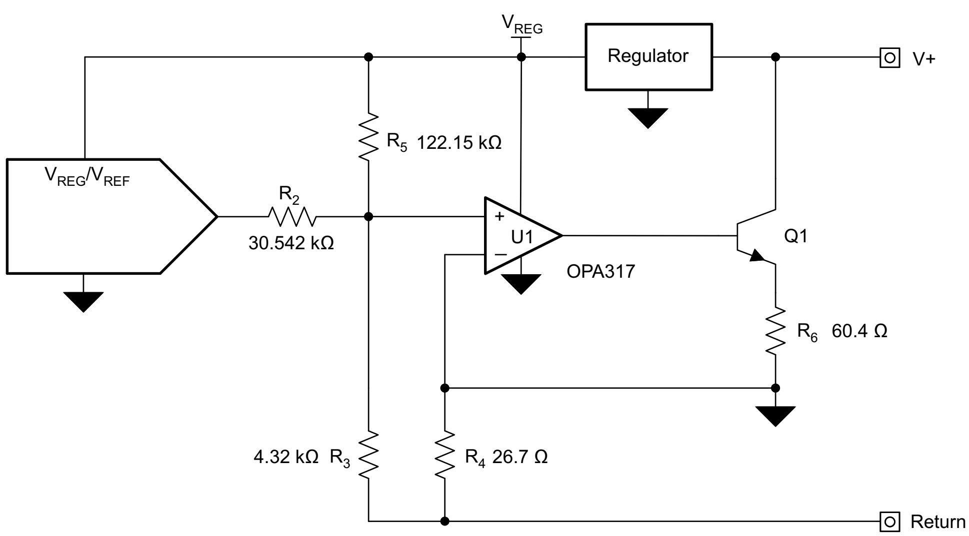


Figure 9-4. Loop Powered Transmitter Schematic

9.2.1.1 Design Requirements

The transmitter has only two external input pins; a supply connection and a ground (or return) connection. The transmitter communicates back to the host, typically a PLC analog input module, by precisely controlling the magnitude of the return current. To conform to the 4-mA to 20-mA communication standards, the complete transmitter must consume less than 4 mA of current.

The complete design of this circuit is outlined in TIPD158, *Low Cost Loop-Powered 4-20mA Transmitter EMC/EMI Tested Reference Design*. The design is expected to be low-cost and deliver immunity to the IEC61000-4 suite of tests with minimum impact on the accuracy of the system. Reference design TIPD158 includes the design goals, simulated results, and measured performance.

9.2.1.2 Detailed Design Procedure

Amplifier U1 uses negative feedback to make sure that the potentials at the inverting (V–) and noninverting (V+) input terminals are equal. In this configuration, V– is directly tied to the local GND; therefore, the potential at the noninverting input terminal is driven to local ground. Thus, the voltage difference across R_2 is the DAC output voltage (VOUT), and the voltage difference across R_5 is the regulator voltage (VREG). These voltage differences cause currents to flow through R_2 and R_5, as illustrated in Figure 9-5.

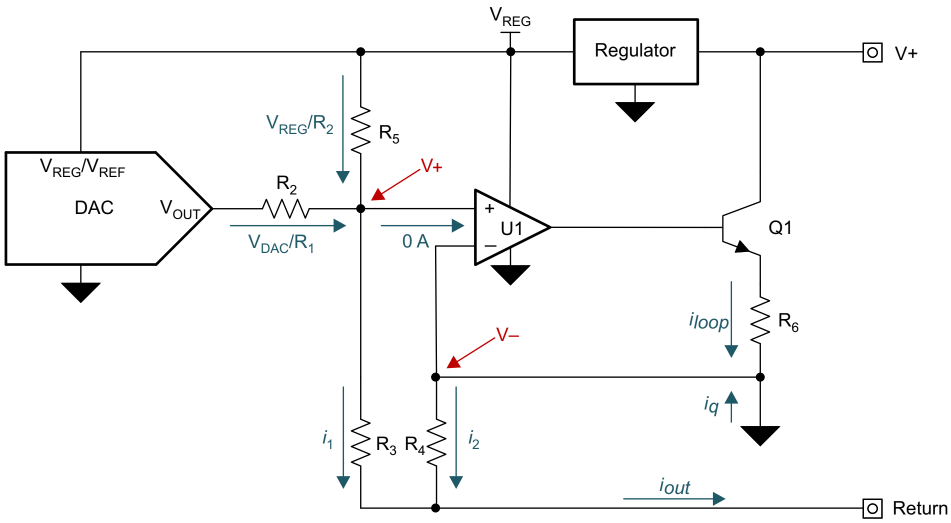


Figure 9-5. Voltage to Current Conversion

The currents from R_2 and R_5 sum into i_1 (defined in Equation 2), and i_1 flows through R_3.

$$i_1 = \frac{V_{DAC}}{R_2} + \frac{V_{REG}}{R_5} \tag{2}$$

Amplifier U2 drives the base of Q1, the NPN bipolar junction transistor (BJT), to allow current to flow through R_4 so that the voltage drops across R_3 and R_4 remain equal. This design keeps the inverting and noninverting terminals at the same potential. A small part of the current through R_4 is sourced by the quiescent current of all of the components used in the transmitter design (regulator, amplifier, and DAC). The voltage drops across R_3 and R_4 are equal; therefore, different-sized resistors cause different current flow through each resistor. Use these different-sized resistors to apply gain to the current flow through R_4 by controlling the ratio of resistor R_3 to R_4, as shown in Equation 3:

$$\begin{aligned} V+ &= i_1 \cdot R_3 \\ V- &= i_2 \cdot R_4 \Rightarrow i_2 = \frac{i_1 \cdot R_3}{R_4} \\ V+ &= V- \end{aligned} \tag{3}$$

The current gain in the circuit helps allow a majority of the output current to come directly from the loop through Q1 instead of from the voltage-to-current converter. This current gain, in addition to the low-power components, keeps the current consumption of the voltage-to-current converter low. Currents i_1 and i_2 sum to form output current i_{out}, as shown in Equation 4:

$$i_{out} = i_1 + i_2 = \frac{V_{DAC}}{R_2} + \frac{V_{REG}}{R_5} + \frac{R_3}{R_4} \cdot \left(\frac{V_{DAC}}{R_2} + \frac{V_{REG}}{R_5}\right) = \left(\frac{V_{DAC}}{R_2} + \frac{V_{REG}}{R_5}\right) \cdot \left(1 + \frac{R_3}{R_4}\right) \tag{4}$$

The complete transfer function, arranged as a function of input code, is shown in Equation 5. The remaining sections divide this circuit into blocks for simplified discussion.

$$i_{out}(Code) = \left(\frac{V_{REG} \cdot Code}{2^{Resolution} \cdot R_2} + \frac{V_{REG}}{R_5} \right) \cdot \left(1 + \frac{R_3}{R_4} \right) \tag{5}$$

Resistor R_6 is included to reduce the gain of transistor Q1, and therefore, reduce the closed-loop gain of the voltage-to-current converter for a stable design. Size resistors R_2, R_3, R_4, and R_5 based on the full-scale range of the DAC, regulator voltage, and the desired current output range of the design.

9.2.1.3 Application Curves

Figure 9-6 shows the measured transfer function of the circuit. Figure 9-7 shows the total unadjusted error (TUE) of the circuit, staying below 0.15 %FSR.

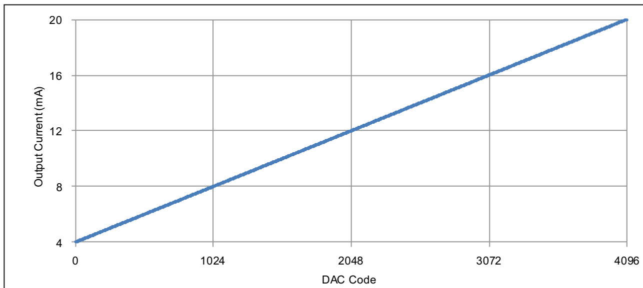


Figure 9-6. Output Current vs Code

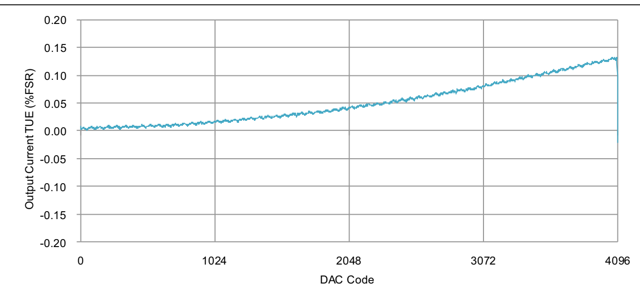


Figure 9-7. Current Total Unadjusted Error vs Code

9.2.2 Using the REF5050 as a Power Supply for the DACx311

As a result of the extremely low supply current required by the DACx311, an alternative option is to use a REF5050 5-V precision voltage reference to supply the required voltage to the part, as shown in Figure 9-8. This option is especially useful if the power supply is too noisy or if the system supply voltages are at some value other than 5 V. The REF5050 outputs a steady supply voltage for the DACx311. If the REF5050 is used, the current needed to supply DACx311 is typically 110 µA at 5 V, with no load on the output of the DAC. When the DAC output is loaded, the REF5050 also needs to supply the current to the load. The total current required (with a 5 kΩ load on the DAC output) is:

$$110\ \mu A + (5\ V / 5\ k\Omega) = 1.11\ mA \tag{6}$$

The load regulation of the REF5050 is typically 0.002%/mA, which results in an error of 90 µV for the 1.1 mA current drawn from the device. This value corresponds to a 0.07 LSB error at 12 bits (DAC7311).

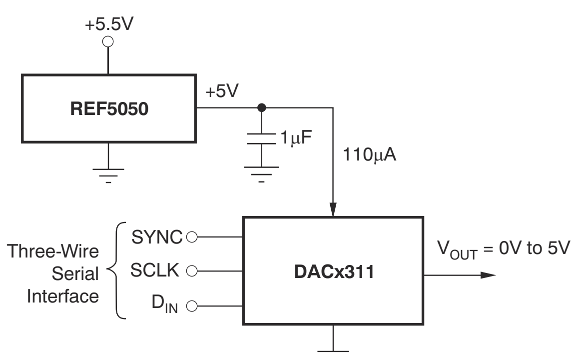


Figure 9-8. REF5050 as Power Supply to DACx311

For other power-supply voltages, alternative references such as the REF3030 (3 V), REF3033 (3.3 V), or REF3220 (2.048 V) are recommended. For a full list of available voltage references from TI, see the TI web site at www.ti.com.

9.2.3 Bipolar Operation Using the DACx311

The DACx311 has been designed for single-supply operation but a bipolar output range is also possible using the circuit in Figure 9-9. The circuit shown gives an output voltage range of ±5 V. Rail-to-rail operation at the amplifier output is achievable using an OPA211, OPA340, or OPA703 as the output amplifier. For a full list of available operational amplifiers from TI, see the TI web site at www.ti.com

The output voltage for any input code can be calculated as follows:

$$V_O = \left[AV_{DD} \times \left(\frac{D}{2^n} \right) \times \left(\frac{R_1 + R_2}{R_1} \right) - AV_{DD} \times \left(\frac{R_2}{R_1} \right) \right] \tag{7}$$

where

- n = resolution in bits; either 8 (DAC5311), 10 (DAC6311), or 12 (DAC7311).
- D = decimal equivalent of the binary code that is loaded to the DAC register. D ranges from 0 to 255 for 8-bit DAC5311, 0 to 1023 for the 10-bit DAC6311 and 0 to 4095 for the 12-bit DAC7311.

With AV_{DD} = 5 V, $R_1 = R_2$ = 10 kΩ:

$$V_O = \left(\frac{10 \times D}{2^n} \right) - 5V \tag{8}$$

The resulting output voltage range is ±5 V. Code 000h corresponds to a –5-V output and FFFh (12-bit level) corresponding to a +5-V output.

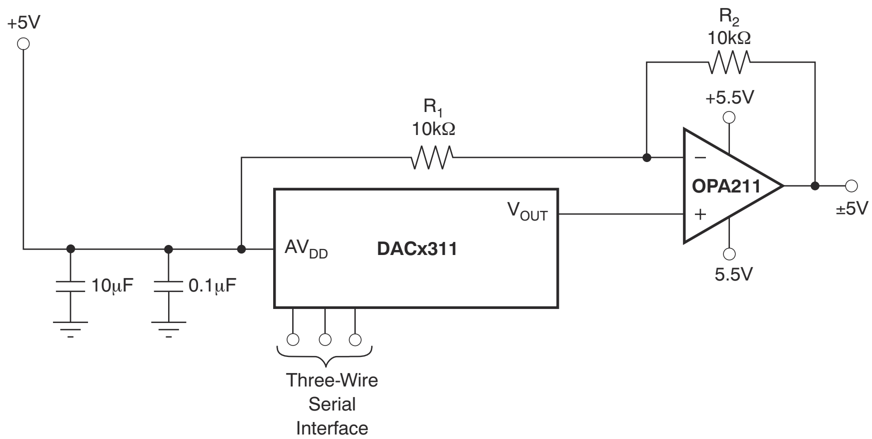


Figure 9-9. Bipolar Operation With the DACx311

9.3 Power Supply Recommendations

The DACx311 is designed to operate with a unipolar analog power supply ranging from 2.0 V to 5.5 V on the AV_{DD} pin. The AV_{DD} pin supplies power to the digital and analog circuits (including the resistor string) inside the DAC. The current consumption of this pin is specified in the *Electrical Characteristics* table. Use a 1 µF to 10 µF capacitor in parallel with a 0.1 µF bypass capacitor on this pin to remove high-frequency noise.

9.4 Layout

9.4.1 Layout Guidelines

A precision analog component requires careful layout, adequate bypassing, and clean, well-regulated power supplies.

The DACx311 offers single-supply operation, and is often used in close proximity to digital logic, microcontrollers, microprocessors, and digital signal processors. The more digital logic present in the design and the higher the switching speed, the more difficult the task is to achieve good performance from the converter.

As a result of the single ground pin of the DACx311, all return currents, including digital and analog return currents, must flow through the GND pin. Ideally, GND is connected directly to an analog ground plane. Separate this plane from the ground connection for the digital components until connected at the power entry point of the system.

The power applied to AV_{DD} must be well-regulated and low-noise. Switching power supplies and dc/dc converters often have high-frequency glitches or spikes riding on the output voltage. In addition, digital components can create similar high-frequency spikes as the internal logic switches state. This noise can easily couple into the DAC output voltage through various paths between the power connections and analog output. This condition is particularly true for the DACx311, as the power supply is also the reference voltage for the DAC.

As with the GND connection, connect AV_{DD} to a 5-V power supply plane or trace that is separate from the connection for digital logic until connected at the power entry point. In addition, 1-µF to 10-µF and 0.1-µF bypass capacitors are strongly recommended. In some situations, additional bypassing can be required, such as a 100 µF electrolytic capacitor or even a *Pi* filter made up of inductors and capacitors—all designed to essentially low-pass filter the 5-V supply and remove high-frequency noise.

9.4.2 Layout Example

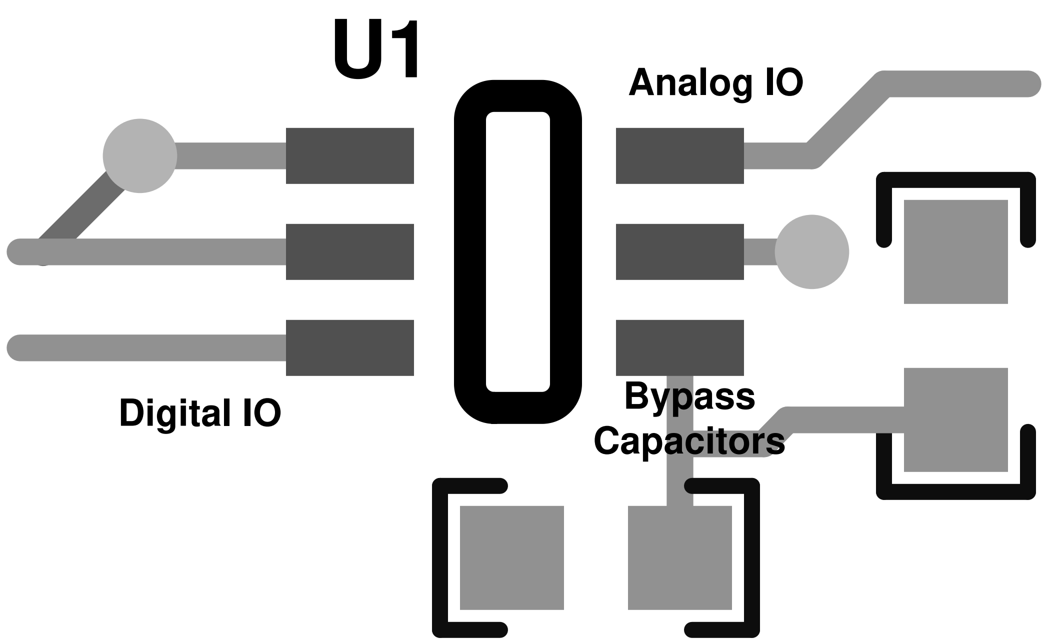


Figure 9-10. Recommended Layout

10 Device and Documentation Support

10.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

10.2 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

10.3 Trademarks

TI E2E™ is a trademark of Texas Instruments.
All trademarks are the property of their respective owners.

10.4 Electrostatic Discharge Caution

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

10.5 Glossary

TI Glossary — This glossary lists and explains terms, acronyms, and definitions.

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
DAC5311IDCKR	ACTIVE	SC70	DCK	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	D53	Samples
DAC5311IDCKT	ACTIVE	SC70	DCK	6	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	D53	Samples
DAC6311IDCKR	ACTIVE	SC70	DCK	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	D63	Samples
DAC6311IDCKT	ACTIVE	SC70	DCK	6	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	D63	Samples
DAC6311IDCKTG4	ACTIVE	SC70	DCK	6	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	D63	Samples
DAC7311IDCKR	ACTIVE	SC70	DCK	6	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	D73	Samples
DAC7311IDCKT	ACTIVE	SC70	DCK	6	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	D73	Samples
DAC7311IDCKTG4	ACTIVE	SC70	DCK	6	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	D73	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

[6] Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF DAC5311 :

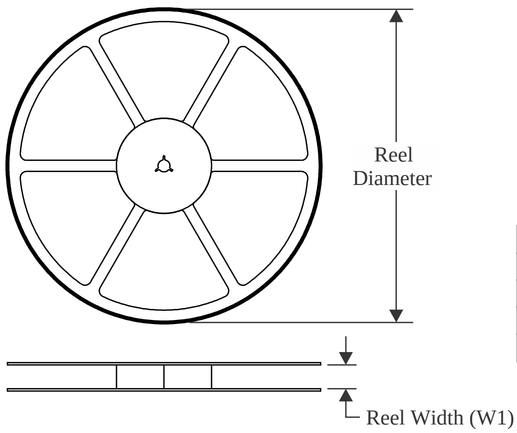
- Automotive : DAC5311-Q1

NOTE: Qualified Version Definitions:

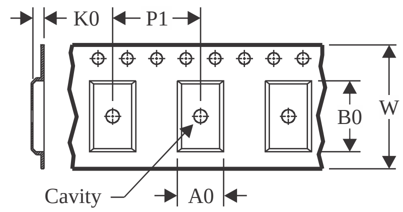
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

TAPE AND REEL INFORMATION

REEL DIMENSIONS

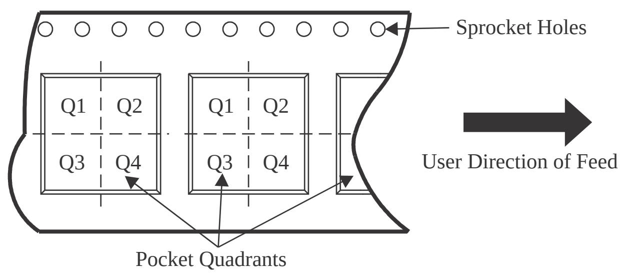


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

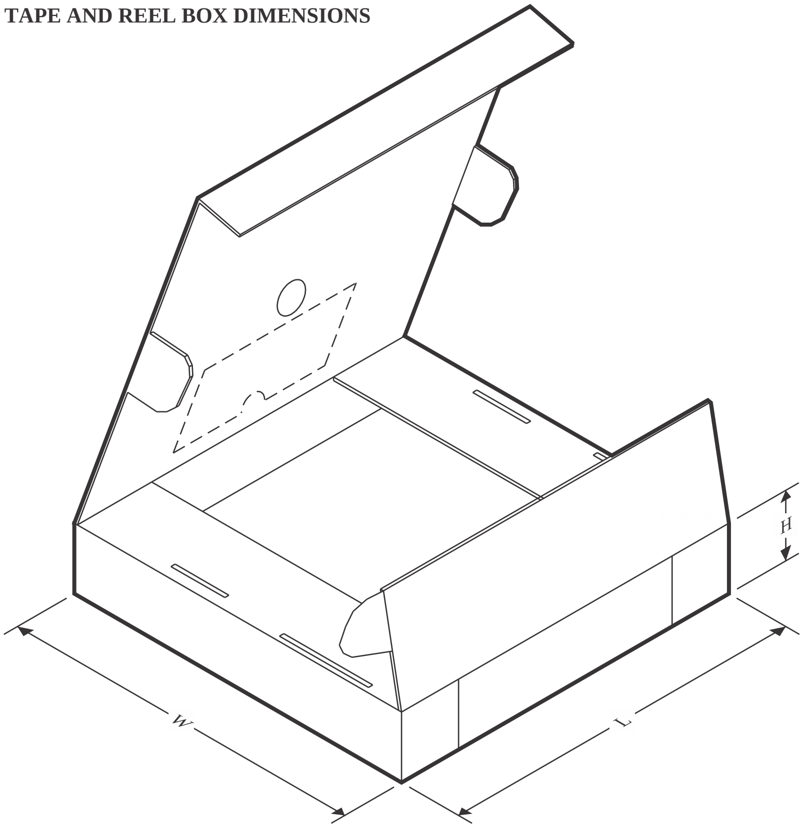
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
DAC5311IDCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
DAC5311IDCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
DAC6311IDCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
DAC6311IDCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
DAC7311IDCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
DAC7311IDCKT	SC70	DCK	6	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3

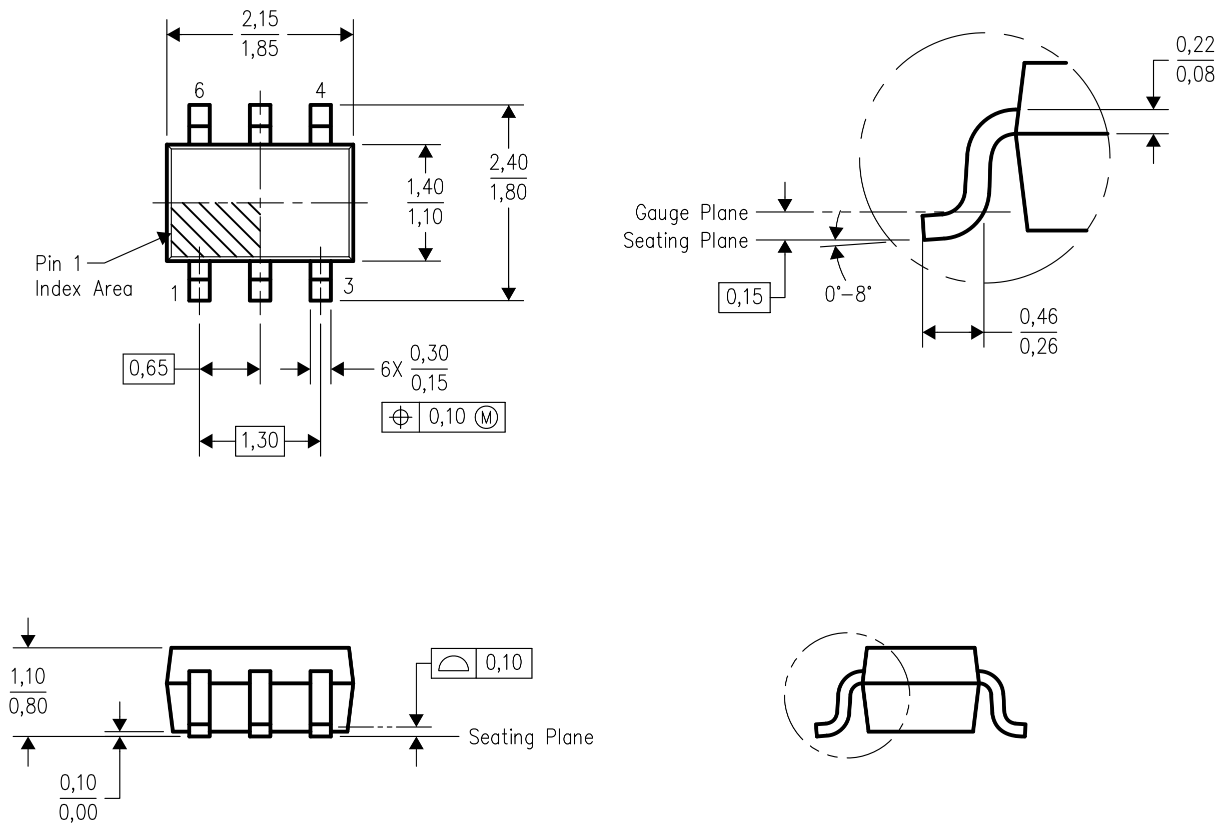
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
DAC5311IDCKR	SC70	DCK	6	3000	180.0	180.0	18.0
DAC5311IDCKT	SC70	DCK	6	250	180.0	180.0	18.0
DAC6311IDCKR	SC70	DCK	6	3000	180.0	180.0	18.0
DAC6311IDCKT	SC70	DCK	6	250	180.0	180.0	18.0
DAC7311IDCKR	SC70	DCK	6	3000	180.0	180.0	18.0
DAC7311IDCKT	SC70	DCK	6	250	180.0	180.0	18.0

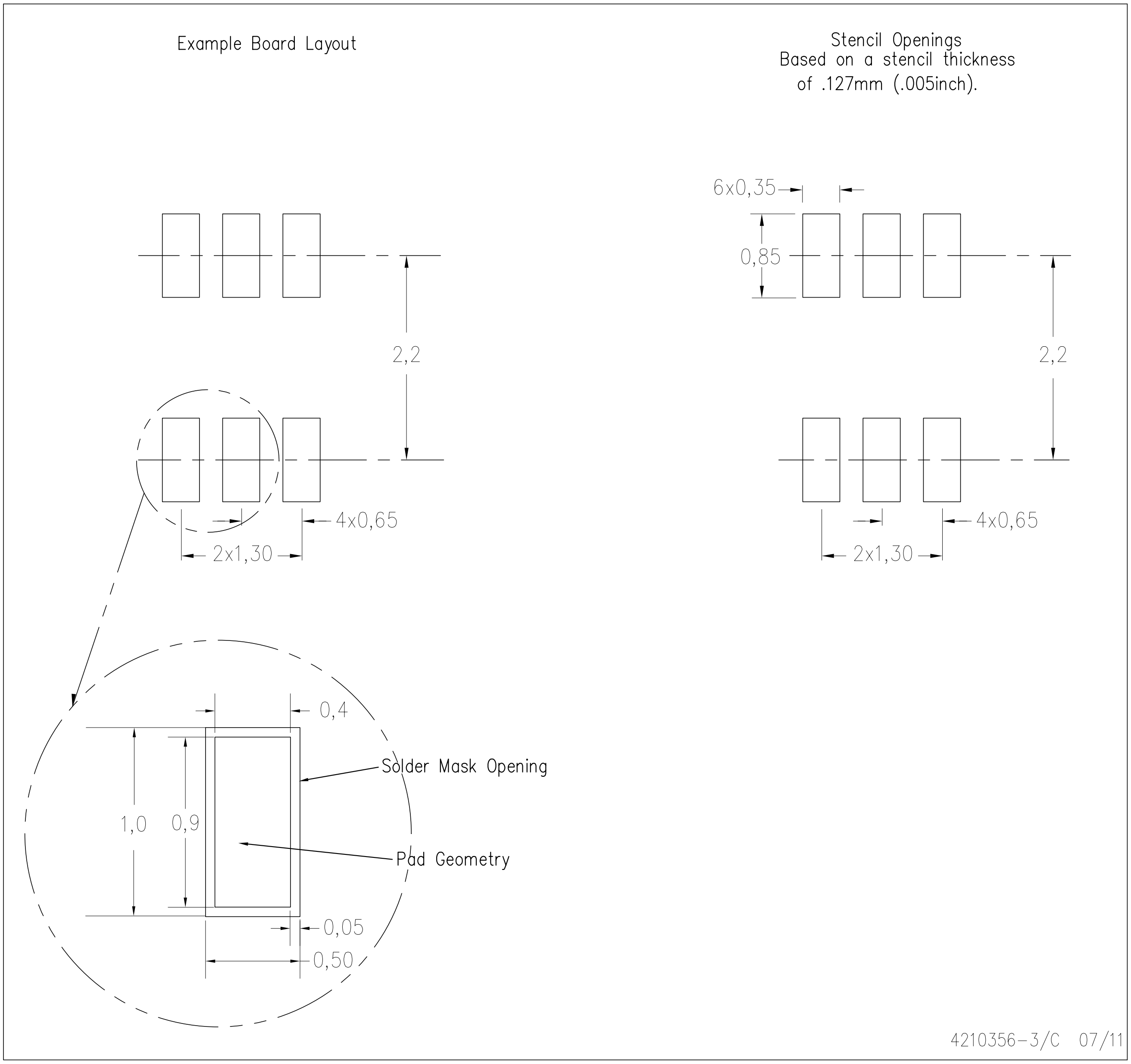
DCK (R-PDSO-G6) PLASTIC SMALL-OUTLINE PACKAGE



4093553-4/G 01/2007

NOTES:
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Falls within JEDEC MO-203 variation AB.

DCK (R-PDSO-G6) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
D. Publication IPC-7351 is recommended for alternate designs.
E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265

单击下面可查看定价，库存，交付和生命周期等信息

[>>TI(德州仪器)]